

Cancelled

Title: POWER MOSFET, N-CHANNEL, RADIATION HARDENED,
HIGH RELIABILITY, SPACE USE,
DETAIL SPECIFICATION FOR
(JAXA R
2SK4152, 2SK4153, 2SK4154,
2SK4155, 2SK4156, 2SK4157,
2SK4158, 2SK4159, 2SK4160,
2SK4217, 2SK4218, 2SK4219)

Document number: JAXA-QTS-2030/102B

Cancellation date: 29 July 2022

JAXA
JAPAN AEROSPACE EXPLORATION AGENCY

Registration No.1227
JAXA-QTS-2030/102B
18 March 2020
Superseding
JAXA-QTS-2030/102A
Cancelled
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RADIATION HARDENED,
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DETAIL SPECIFICATION FOR

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2SK4152, 2SK4153, 2SK4154
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2SK4158, 2SK4159, 2SK4160
2SK4217, 2SK4218, 2SK4219

Prepared and Established by Fuji Electric Co.,Ltd.
Issued by Japan Aerospace Exploration Agency

This document is the English version of JAXA QTS/ADS which was originally written and authorized in Japanese and carefully translated into English for international users. If any question arises as to the context or detailed description, it is strongly recommended to verify against the latest official Japanese version.

The release date of the English version of this specification: March 14, 2022.

Revision Log

Rev.	Date	Description
----	29 Feb. 2008	Original
A	12 Nov. 2012	▪ Table 1b: Corrected an error for the condition of Dynamic characteristics Corrected ID of 2SK4159 in Group A-4 of Dynamic characteristics from "27A" to "26A". ▪ Table 2b: Changed "Thermal resistance ($R_{th(ch-c)}(\Delta V_{SD})$)" to "Thermal impedance ($Z_{th(ch-c)}(\Delta V_{SD})$)" in compliance with the terms in MIL-STD-750. ▪ Table 2b: Added a test condition (Minimum On time: 30 seconds) of Intermittent Operation Life test. ▪ Table 3: Changed "Thermal resistance ($R_{th(ch-c)}(\Delta V_{SD})$)" to "Thermal impedance ($Z_{th(ch-c)}(\Delta V_{SD})$)" in compliance with the terms in MIL-STD-750. ▪ Table 3: Added a test condition (Minimum On time: 30 seconds) of Intermittent Operation Life test. ▪ Table 3: Added "(5) If the inspection lot is the one used in the Group B test, this test may be exempted" in compliance with General specification. ▪ Table 4a: Reviewed the number of significant figures in the test conditions of D-2a, D-2b and D-2c. ▪ Table 6 Exemption of Quality Conformance Inspection: Deleted test items, for which the quality conformance inspection is not performed. ▪ Added the maximum safe operating area of DC to figures. ▪ Others: Corrected errors to ensure consistency.
B	18 March 2020	▪ Cover: Changed the corporate name. ▪ Paragraph 3.2.1: Added marking for inspection lot identification code and serial number. ▪ Modified the wording in each paragraph in the document. ▪ Table 7a Qualification inspection (A-3b): Corrected test condition error of gfs from "$V_{GS}=25V$" to "$V_{DS}=25V$". ▪ Table 2a Group B inspection (B-3g), Table 2b Group B inspection (B-6g), and Table 8a Qualification test, Group B inspection (B-3g) and Table 8b Qualification test, Group B inspection (B-6g): Corrected test condition error of Bond strength from "condition A" to "condition D".

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**POWER MOSFET, N-CHANNEL, RADIATION HARDENED,
HIGH RELIABILITY, SPACE USE,
DETAIL SPECIFICATION FOR**

JAXA R

2SK4152, 2SK4153, 2SK4154
2SK4155, 2SK4156, 2SK4157
2SK4158, 2SK4159, 2SK4160
2SK4217, 2SK4218, 2SK4219

1 GENERAL

This specification establishes the detailed requirements for space use, high reliability, N channel power MOSFET (100, 130, 200 and 250V for SMD types) used for electronic equipment installed on spacecrafts. The products specified in this specification are as follows.

1.1 Part Number

The part numbers for the products covered by this specification are as follows:

JAXA⁽¹⁾ R⁽²⁾ 2SK4152
JAXA⁽¹⁾ R⁽²⁾ 2SK4153
JAXA⁽¹⁾ R⁽²⁾ 2SK4154
JAXA⁽¹⁾ R⁽²⁾ 2SK4155
JAXA⁽¹⁾ R⁽²⁾ 2SK4156
JAXA⁽¹⁾ R⁽²⁾ 2SK4157
JAXA⁽¹⁾ R⁽²⁾ 2SK4158
JAXA⁽¹⁾ R⁽²⁾ 2SK4159
JAXA⁽¹⁾ R⁽²⁾ 2SK4160
JAXA⁽¹⁾ R⁽²⁾ 2SK4217
JAXA⁽¹⁾ R⁽²⁾ 2SK4218
JAXA⁽¹⁾ R⁽²⁾ 2SK4219

Notes ⁽¹⁾ "JAXA" indicates the common parts for space applications.

⁽²⁾ "R" indicates the radiation hardness assurance designator.

1.2 Absolute Maximum Ratings

The absolute maximum ratings of the products specified in this specification are as follows.

Unless otherwise specified, T_A is +25°C.

Part No.	V_{DS} (V)	I_D (A)	$I_{D(pulse)}$ (A)	V_{GS} (V)	P_D $T_C=25^\circ\text{C}$ (W)	$T_{ch}^{(1)}$ (°C)	T_{stg} (°C)	$R_{th(ch-c)}$ (°C/W)	SOA
JAXA R 2SK4152	130	42	168	±20	250 Fig. 5	150	-55 to 150	0.5	Fig. 6
JAXA R 2SK4153	130	39	156		150 Fig. 7			0.83	Fig. 8
JAXA R 2SK4154	130	15	60		70 Fig. 9			1.67	Fig. 10
JAXA R 2SK4155	200	42	168		250 Fig. 11			0.5	Fig. 12
JAXA R 2SK4156	200	32	128		150 Fig. 13			0.83	Fig. 14
JAXA R 2SK4157	200	14	56		70 Fig. 15			1.67	Fig. 16
JAXA R 2SK4158	250	42	168		250 Fig. 17			0.5	Fig. 18
JAXA R 2SK4159	250	26	104		150 Fig. 19			0.83	Fig. 20
JAXA R 2SK4160	250	12	48		70 Fig. 21			1.67	Fig. 22
JAXA R 2SK4217	100	42	168		250 Fig. 23			0.5	Fig. 24
JAXA R 2SK4218	100	42	168		150 Fig. 25			0.83	Fig. 26
JAXA R 2SK4219	100	15	60		70 Fig. 27			1.67	Fig. 28

Note⁽¹⁾ The channel temperature T_{ch} is given by the following equations:

$$T_{ch} = T_C + R_{th(ch-c)} \times P_D$$

Where, T_C : Case temperature (°C)

$R_{th(ch-c)}$: Thermal resistance between channel and case (°C/W)

P_D : Power dissipation (W)

1.3 Primary Electrical Characteristics

The primary electrical characteristics of the products specified in this specification are as follows. Unless otherwise specified, T_A is +25°C.

Electrical Characteristics (1/3)

Part No.	$V_{(BR)DSS}$ (V)	I_{DSS} (μA)	I_{GSS} (nA)	$V_{GS(th)}$ (V)	$R_{DS(on)}^{(1)}$ (m Ω)	$gfs^{(1)}$ (S)	E_{AS} (mJ)
	$I_D=1mA$ $V_{GS}=0V$	$V_{DS}=80\%$ of rated V_{DS} $V_{GS}=0V$	$V_{GS}=\pm 20V$ $V_{DS}=0V$	$I_D=1mA$ $V_{DS}=V_{GS}$	$I_D=50\%$ of rated I_D $V_{GS}=12V$	$I_D=50\%$ of rated I_D $V_{DS}=25V$	Rated I_D $V_{DD}=48V$, $V_{GS}=12V$
	Min	Max	Max	Min-Max	Max	Min	Max
JAXA R 2SK4152	130	10	± 100	2.5-4.5	17	8	1097
JAXA R 2SK4153	130				39	8	343
JAXA R 2SK4154	130				89	4	261
JAXA R 2SK4155	200				26	8	713
JAXA R 2SK4156	200				62	8	271
JAXA R 2SK4157	200				148	4	182
JAXA R 2SK4158	250				38	8	570
JAXA R 2SK4159	250				91	8	267
JAXA R 2SK4160	250				223	4	170
JAXA R 2SK4217	100				13	8	1426
JAXA R 2SK4218	100				28	8	414
JAXA R 2SK4219	100				64	4	340

Note⁽¹⁾ Pulse test: Pulse width $\leq 1ms$, Duty cycle $\leq 2\%$

Electrical Characteristics (2/3)

Part No.	Q_{GS} (nC)	Q_{GD} (nC)	Q_G (nC)	$t_{d(on)}$ (ns)	t_r (ns)	$t_{d(off)}$ (ns)	t_f (ns)
	$V_{DS}=50\%$ of rated V_{DS} , I_D = rated I_D , $V_{GS}=12V$			$V_{DD}=50\%$ of rated V_{DS} , I_D = rated I_D , $V_{GS}=12V$, $R_G=10\Omega$			
	Max	Max	Max	Max	Max	Max	Max
JAXA R 2SK4152	60	70	220	65	30	190	65
JAXA R 2SK4153	30	30	100	40	20	100	30
JAXA R 2SK4154	13	10	50	30	20	65	15
JAXA R 2SK4155	60	70	220	65	30	190	35
JAXA R 2SK4156	30	30	100	40	20	100	20
JAXA R 2SK4157	13	10	50	30	20	65	15
JAXA R 2SK4158	60	70	220	65	30	190	30
JAXA R 2SK4159	30	30	100	40	20	100	15
JAXA R 2SK4160	13	10	50	30	20	65	10
JAXA R 2SK4217	60	70	220	65	30	190	65
JAXA R 2SK4218	30	30	100	40	20	100	30
JAXA R 2SK4219	13	10	50	30	20	65	15

Electrical Characteristics (3/3)

(Body Diode Characteristics)

Part No.	$V_{SD}^{(1)}$ (V)	t_{rr} (ns)	Q_{rr} (μC)
	I_F = rated I_D $V_{GS}=0V$	I_F = rated I_D , $V_{GS}=0V$, $-di/dt=100A/\mu S$, $T_{ch}=25^\circ C$	
	Max	Typ	Typ
JAXA R 2SK4152	1.6	520	11.0
JAXA R 2SK4153		540	9.0
JAXA R 2SK4154		390	5.0
JAXA R 2SK4155		690	13.5
JAXA R 2SK4156		800	12.0
JAXA R 2SK4157		620	6.0
JAXA R 2SK4158		1000	19.0
JAXA R 2SK4159		900	12.0
JAXA R 2SK4160		640	6.5
JAXA R 2SK4217		450	7.0
JAXA R 2SK4218		500	6.5
JAXA R 2SK4219		350	3.5

Note⁽¹⁾ Pulse test: Pulse width $\leq 1ms$, Duty cycle $\leq 2\%$

1.4 Radiation Hardness

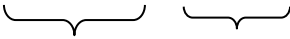
The radiation hardness of the products specified in this specification is as follows.

Symbol	Radiation hardness assurance level
R	1000 Gy(Si) {1×10 ⁵ rad(Si)} (Dose Rate 36Gy(Si)/ h to 360Gy(Si)/ h)

2 APPLICABLE DOCUMENTS

The latest issues of documents listed below at the time of contract award or application form a part of this specification the extent specified herein.

JAXA-QTS-2030	Semiconductor Devices, High Reliability, Space Use, General Specification for
MIL-STD-750	Test Method Standard, Test Methods for Semiconductor Devices
MIL-PRF-19500N	Performance Specification Semiconductor Devices, General Specification for

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3 REQUIREMENTS			
3.1 Design and Construction The design and construction of the products shall meet the requirements specified in this paragraph and paragraph 3.3 of JAXA-QTS-2030.			
3.1.1 Package Configuration and Terminal Connection The package configuration and terminal connection shall meet the requirements specified in Figures 1a, 1b and 1c.			
3.1.2 Terminal Materials and Finish The material of terminals shall be Cu-W alloy. The terminals shall be finished with gold plating. The purity of gold shall be a minimum of 99.7%. The thickness of the plating shall be a minimum of 1.27µm. This finish shall be plated with nickel as an underplating of a thickness between 1.27µm and 7.62µm.			
3.1.3 Electrical Characteristics The electrical characteristics shall meet the requirements specified in Tables 1a and 1b.			
3.2 Marking Marking shall be in accordance with the paragraph 3.4 of JAXA-QTS-2030, and Figures 2a, 2b and 2c.			
3.2.1 Marking for Inspection Lot Identification Code and Serial Number The marking for inspection lot identification code and serial number shall be as follows. Example: 19 01 001 a) b) c)  Inspection lot Serial number identification code a) The last two digit number indicating the year the inspection started b) The two digit number indicating the week of sealing for the first inspection subplot (production lot) of each inspection lot. The week number is counted from the first week of January of the year. c) Unique three-digit number from 001 to 999 consecutively assigned for each product within the inspection lot			

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3.3 Certification The requirements for the products to be certified shall be in accordance with paragraph 3.1 of JAXA-QTS-2030. 4 QUALITY ASSURANCE PROVISIONS 4.1 General Requirements The general requirements shall be in accordance with paragraph 4.1 of JAXA-QTS-2030. 4.2 Incoming Materials Control The incoming materials control shall be in accordance with paragraph 4.2 of JAXA-QTS-2030. 4.3 Manufacturing Process Control The manufacturing process control shall be in accordance with paragraph 4.3 of JAXA-QTS-2030. 4.4 In-process Inspection The in-process inspection shall be in accordance with paragraph 4.5 of JAXA-QTS-2030. 4.5 Screening The screening shall be in accordance with paragraph 4.7 of JAXA-QTS-2030. The electrical characteristics to be measured, test conditions and delta limits shall be as follows.			

4.5.1 Electrical Characteristics to be Measured

The following parameters shall be measured during the interim and final electrical characteristics tests for screening.

(1) Interim electrical characteristic tests

$T_A = +25^\circ\text{C}$

Measuring item	$V_{(BR)DSS}$ (V)	I_{DSS} (μA)	I_{GSS} (nA)	$V_{GS(th)}$ (V)	$R_{DS(on)}^{(1)}$ ($\text{m}\Omega$)	$g_{fs}^{(1)}$ (S)	$V_{SD}^{(1)}$ (V)
MIL-STD-750 Test Method No.	3407	3413	3411	3404	3421	3475	---
Test conditions	Bias Condition C $I_D = 1\text{mA}$ $V_{GS} = 0\text{V}$	Bias Condition C $V_{DS} = 80\%$ of rated V_{DS} $V_{GS} = 0\text{V}$	Bias Condition C $V_{GS} = \pm 20\text{V}$ $V_{DS} = 0\text{V}$	$I_D = 1\text{mA}$ $V_{DS} = V_{GS}$	$I_D = 50\%$ of rated I_D $V_{GS} = 12\text{V}$	$I_D = 50\%$ of rated I_D $V_{DS} = 25\text{V}$	$I_F = \text{rated } I_D$ $V_{GS} = 0\text{V}$
	Min	Max	Max	Min-Max	Max	Min	Max
JAXA R 2SK4152	130	10	± 100	2.5-4.5	17	8	1.6
JAXA R 2SK4153	130				39	8	
JAXA R 2SK4154	130				89	4	
JAXA R 2SK4155	200				26	8	
JAXA R 2SK4156	200				62	8	
JAXA R 2SK4157	200				148	4	
JAXA R 2SK4158	250				38	8	
JAXA R 2SK4159	250				91	8	
JAXA R 2SK4160	250				223	4	
JAXA R 2SK4217	100				13	8	
JAXA R 2SK4218	100				28	8	
JAXA R 2SK4219	100				64	4	

Note⁽¹⁾ Pulse test: Pulse width $\leq 1\text{ms}$, Duty cycle $\leq 2\%$

(2) Final electrical characteristics test: As specified in the subgroups 1, 2 and 3 of Tables 1a and 1b.

4.5.2 Test Conditions

The conditions of gate stress test, avalanche energy test, temperature cycling test, reverse bias burn-in test and burn-in test for screening test shall be as follows.

(Gate stress test is performed as part of In-process inspection.)

Gate stress test: $V_{GS}=35V$, $t=1ms$, $T_A=25^{\circ}C$

Single pulse avalanche energy (E_{AS}) test: $I_{D(pulse)} = \text{rated } I_D$, $V_{DD}=48V$, $V_{GS}=12V$,
single pulse

Initial $T_C = +25_{-5}^{+10} {}^{\circ}C$

$$L(mH) = \left[\frac{2E_{AS}}{(I_D)^2} \right] \left[\frac{BV_{DSS} - V_{DD}}{BV_{DSS}} \right] \quad \bullet \bullet \text{ Equation (1)}$$

Temperature cycling test: Condition G, 20 cycles

Reverse bias burn-in test (GS): $T_A=150^{\circ}C$, $V_{GS}=16V$
 $V_{DS}=0V$, 48hr

Burn-in test (DS): $T_A=150^{\circ}C$, $V_{DS}=80\%$ of rated V_{DS}
 $V_{GS}=0V$, 240hr

4.5.3 Delta Limits

The delta limits for reverse bias burn-in test and burn-in test shall be as follows.

$$\Delta I_{GSS} \leq |20nA|$$

$$\Delta I_{DSS} \leq |10\mu A|$$

$$\Delta R_{DS(on)} \leq |20\%|$$

$$\Delta V_{GS(th)} \leq |20\%|$$

4.6 Qualification Test and Quality Conformance Inspection

The qualification test and the quality conformance inspection shall be in accordance with paragraphs 4.6 and 4.8 of JAXA-QTS-2030. External dimensions, electrical characteristics, test conditions and limits shall be as specified in Figure 1, and Tables 1, 2, 3 and 4.

Group C inspection and Group D inspection may be exempted when the qualification test or quality conformance inspection for the Groups C and D inspections was performed and the device passed the test within a year. Detailed requirements are specified in Table 6.

Group E inspection may be exempted in spite of chip size, when the semiconductor devices manufactured from the die of the same wafer lot have passed the Group E inspection in the qualification test or the quality conformance inspection.

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4.6.1	Electrostatic Discharge Sensitivity Test Electrostatic discharge sensitivity test in the qualification test shall be performed with the following lead combination: Gate and Source 4.6.2 Radiation Hardness Test Radiation test (TID: Total Dose Irradiation) level, electrical characteristics, test conditions and limits in the qualification tests and the quality conformance inspections shall be as specified in Table 5. The bias shall be maintained during the irradiation and post-irradiation electrical characteristics test. The post-irradiation electrical characteristics test shall be performed within 24 hours after the completion of irradiation. 4.7 Change of Tests and Inspections No change has been made to any test or inspection specified in appendixes A, B or C of JAXA-QTS -2030. 4.8 Shipment after Long-term Storage Shipment of the products stored at the manufacturer's site for 24 months or longer shall be in accordance with paragraph 4.9.1 of JAXA-QTS-2030. 5 PREPARATION FOR DELIVERY Preparation for delivery shall be in accordance with paragraph 5 of JAXA-QTS-2030. 6 NOTES 6.1 Terms and Definitions The terms and definitions used herein shall be in accordance with paragraph 1.2 of JAXA-QTS-2030 and as follows. (1) SEB (Single Event Burnout); Burnout of the device caused by the incidence of a proton or a heavy ion, when the device is applied to an off-state voltage between drain and source. (2) SEGR (Single Event Gate Rupture); Breakdown of MOSFET Gate Oxide film caused by the incidence of a proton or a heavy ion, when the device is applied to a gate bias voltage between gate and source. 6.2 Notes for Purchasers The precautions to be taken by the purchaser shall be in accordance with paragraph 6.2 of JAXA-QTS-2030 and as follows.		

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6.2.1 Handling Instructions The products specified in this specification contain thin oxide films and can be damaged due to electrostatic discharge (ESD). ESD protection measures shall be implemented to avoid ESD between the gate and source and between the gate and drain during transportation and other handling environments. 6.3 Coordination with MIL-PRF-19500N The comparison of qualification test items between MIL-PRF-19500N and JAXA-QTS-2030/102 is shown in Tables 7 through 11.			

Table 1a. Group A Inspection ⁽¹⁾

Gr.No	MIL-STD-750			100V Class			130V Class			200V Class			250V Class		
Sub	Test Item	Method	JAXA R	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160
A-1 Static Characteristics (T _A =25°C)			Sample Size												
			LTPD 3												
-1a	Breakdown Voltage Drain to Source V _{DSS}	3407	Conditions	Bias Condition C I _D =1mA, V _{GS} =0V											
			Limits	min 100V DC			min 130V DC			min 200V DC			min 250V DC		
-1b	Gate-to-Source Leakage Current I _{GSS}	3411	Conditions	Bias Condition C V _{GS} =±20V, V _{DS} =0V											
			Limits	max ±100nA DC											
-1c	Drain Current I _{DSS}	3413	Conditions	Bias Condition C V _{DS} =80V, V _{GS} =0V			Bias Condition C V _{DS} =104V, V _{GS} =0V			Bias Condition C V _{DS} =160V, V _{GS} =0V			Bias Condition C V _{DS} =200V, V _{GS} =0V		
			Limits	max 10μA DC											
-1d	Gate to Source Voltage (Threshold) V _{GS(th)}	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA											
			Limits	2.5 - 4.5V DC											
-1e	Static Drain to Source On-State Resistance R _{DS(on)}	3421	Conditions	Pulse Test ⁽²⁾ , V _{GS} =12V											
			I _D 21A 21A 7.5A			I _D 21A 19.5A 7.5A			I _D 21A 16A 7A			I _D 21A 13A 6A			
			max [mΩ] 13 28 64			max [mΩ] 17 39 89			max [mΩ] 26 62 148			max [mΩ] 38 91 223			
-1f	Forward Transconductance g _{fs}	3475	Conditions	Pulse Test ⁽²⁾ , V _{DS} =25V											
			I _D 21A 21A 7.5A			I _D 21A 19.5A 7.5A			I _D 21A 16A 7A			I _D 21A 13A 6A			
			min 8S 8S 4S			min 8S 8S 4S			min 8S 8S 4S			min 8S 8S 4S			
-1g	Forward Voltage V _{SD}	---	Conditions	Pulse Test ⁽²⁾ , V _{GS} =0V											
			I _F 42A 42A 15A			I _F 42A 39A 15A			I _F 42A 32A 14A			I _F 42A 26A 12A			
			max 1.6V												
A-2 Static Characteristics (T _A =125°C)			Sample Size												
-2a	Gate-to-Source Leakage Current I _{GSS} (125°C)	3411	Conditions	Bias Condition C V _{GS} =±20V, V _{DS} =0V											
			Limits	max ±100nA DC											
-2b	Drain Current I _{DSS} (125°C)	3413	Conditions	Bias Condition C V _{DS} =80V, V _{GS} =0V			Bias Condition C V _{DS} =104V, V _{GS} =0V			Bias Condition C V _{DS} =160V, V _{GS} =0V			Bias Condition C V _{DS} =200V, V _{GS} =0V		
			Limits	max 25μA DC											
-2c	Gate to Source Voltage (Threshold) V _{GS(th)} (125°C)	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA											
			Limits	min 1.5V DC											
-2d	Static Drain to Source On-State Resistance R _{DS(on)} (125°C)	3421	Conditions	Pulse Test ⁽²⁾ , V _{GS} =12V											
			I _D 21A 21A 7.5A			I _D 21A 19.5A 7.5A			I _D 21A 16A 7A			I _D 21A 13A 6A			
			max [mΩ] 23 49 110			max [mΩ] 31 71 162			max [mΩ] 52 125 297			max [mΩ] 76 183 448			

Notes⁽¹⁾ The same sample may be used for all subgroups.

⁽²⁾ Pulse test: Pulse width ≤ 1ms, Duty cycle ≤ 2%

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Table 1b. Group A Inspection ⁽¹⁾																
Gr.No	MIL-STD-750				100V Class			130V Class			200V Class			250V Class		
Sub	Test Item	Method	JAXA R	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160	
A -3	Static Characteristics (T _A =-55°C)		Sample Size	LTPD 5												
	-3a	Gate to Source Voltage (Threshold) V _{GS(th)} (-55°C)	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA											
				Limits	max 5.0V DC											
	-3b	Forward Transconductance g _{fs} (-55°C)	3475	Conditions	Pulse Test ⁽²⁾ , V _{DS} =25V											
				Limits	I _D 21A 21A 7.5A min 8.5S 8.5S 4.5S			I _D 21A 19.5A 7.5A min 8.5S 8.5S 4.5S			I _D 21A 16A 7A min 8.5S 8.5S 4.5S			I _D 21A 13A 6A min 8.5S 8.5S 4.5S		
A -4	Dynamic Characteristics (T _A =25°C)		Sample Size	LTPD 3												
	Switching Time Test (1) Turn-on delay time: t _{d(on)} Rise time: t _r (2) Turn-off delay time: t _{d(off)} Fall time: t _f	3472	Conditions	V _{DD} =50V V _{GS} =12V , R _g =10Ω I _D 42A 42A 15A			V _{DD} =65V V _{GS} =12V , R _g =10Ω I _D 42A 39A 15A			V _{DD} =100V V _{GS} =12V , R _g =10Ω I _D 42A 32A 14A			V _{DD} =125V V _{GS} =12V , R _g =10Ω I _D 42A 26A 12A			
			Limits	max			max			max			max			
			t _{d(on)}	65ns 40ns 30ns	65ns 40ns 30ns	65ns 40ns 30ns	65ns 40ns 30ns									
			t _r	30ns 20ns 20ns	30ns 20ns 20ns	30ns 20ns 20ns	30ns 20ns 20ns									
			t _{d(off)}	190ns 100ns 65ns	190ns 100ns 65ns	190ns 100ns 65ns	190ns 100ns 65ns									
			t _f	65ns 30ns 15ns	65ns 30ns 15ns	35ns 20ns 15ns	30ns 15ns 10ns									
			A -6a	Safe Operating Area Test ⁽³⁾		Sample Size	LTPD 5									
	3474	Conditions		---												
-6b	End-Point Electrical Measurements	---		Conditions	Same as Gr.A-1											
A -7	Other Characteristics (T _A =25°C) ⁽⁴⁾		Sample Size	LTPD 10												
	-7a	Gate Charge (1) Gate Charge: Q _g (2) Gate to Drain Charge: Q _{gd} (3) Gate to Source Charge: Q _{gs}	3471	Conditions	V _{GS} =12V V _{DS} =50V I _D 42A 42A 15A			V _{GS} =12V V _{DS} =65V I _D 42A 39A 15A			V _{GS} =12V V _{DS} =100V I _D 42A 32A 14A			V _{GS} =12V V _{DS} =125V I _D 42A 26A 12A		
				Limits	max			max			max			max		
				Q _g	220nC 100nC 50nC	220nC 100nC 50nC	220nC 100nC 50nC	220nC 100nC 50nC								
				Q _{gd}	70nC 30nC 10nC	70nC 30nC 10nC	70nC 30nC 10nC	70nC 30nC 10nC								
				Q _{gs}	60nC 30nC 13nC	60nC 30nC 13nC	60nC 30nC 13nC	60nC 30nC 13nC								
	-7b	Reverse Recovery Characteristics (1) t _{rr} (2) Q _{rr}	3473	Conditions	I _F = I _D 42A 42A 15A			I _F = I _D 42A 39A 15A			I _F = I _D 42A 32A 14A			I _F = I _D 42A 26A 12A		
				Limits	max			max			max			max		
t _{rr}				765ns 750ns 525ns	765ns 750ns 525ns	1050ns 1200ns 950ns	1500ns 1350ns 950ns									
Q _{rr}	10.5μC 10.0μC 5.5μC	13.0μC 12.0μC 6.5μC	20.0μC 18.0μC 9.0μC	29.0μC 18.0μC 10.0μC												
Notes ⁽¹⁾ The same sample may be used for all subgroups. ⁽²⁾ Pulse test: Pulse width ≤ 1ms, Duty cycle ≤ 2% ⁽³⁾ The samples used for subgroups A-1, A-2, and A-3 tests shall be used. ⁽⁴⁾ The samples used for subgroups A-6 tests shall be used.																

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Table 2a. Group B Inspection																	
Gr.No	MIL-STD-750				100V Class			130V Class			200V Class			250V Class			
Sub	Test Item	Method	JAXA R	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160		
B -1	External Dimensions ⁽¹⁾		Sample Size	Level I ⁽²⁾ 3p													
				Level II ⁽²⁾ 3p													
		2066	Conditions	See Fig. 1a, 1b, 1c													
B -2	Resistance to Solvents ⁽³⁾ ⁽⁴⁾		Sample Size	Level I 3p													
				Level II 3p													
		1022	Conditions	Solvent a, b, c													
B -3b	Temperature Cycling (Air to Air)		Sample Size	Level I 6p													
				Level II 6p													
		1051	Conditions	-55 ⁺⁰ _{-.5} °C↔25 ⁺¹⁰ _{-.5} °C↔150 ⁺⁵ _{-.0} °C 100 cycles													
-3c	Surge Test (1) Gate Shock	4066	Conditions	V _{GS} =35V													
				V _{DS} =48V, L= See paragraph 4.5.2, Equation (1), R _g =10Ω													
	(2) Avalanche	3470	Conditions	42A	42A	15A	42A	39A	15A	42A	32A	14A	42A	26A	12A		
-3d	Hermetic Seal (1) Fine	1071	Conditions	Condition H													
			Limits	max 1×10 ⁻³ Pa·cm ³ /s													
	(2) Gross	1071	Conditions	Condition C													
-3e	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-1													
-3f	Decap-Internal Visual and mechanical inspection	2075 2071	Conditions	---													
-3g	Bond Strength	2037	Conditions	Condition D													
			Limits	Gate Wire >90gf													
				Source Wire >300gf >300gf >90gf >300gf >300gf >90gf >300gf >300gf >90gf >300gf >300gf >90gf													
-3h	SEM ⁽¹⁾	2077	Conditions	---													
-3i	Die Shear		Sample Size	Level I 3p													
				Level II 3p													
		2017	Conditions	---													
			Limits	min 2.5kgf													
B -4	Solderability ⁽³⁾ ⁽⁴⁾		Sample Size	Level I 6 terminals ⁽⁵⁾													
				Level II 6 terminals ⁽⁵⁾													
		2026	Conditions	---													

Notes⁽¹⁾ The test may be performed using the samples prior to inspection lot formation.

⁽²⁾ Level I and Level II shall be applicable to the qualification test and the quality conformance inspection, respectively. (See paragraphs C.3.2 and C.3.3 of JAXA-QTS-2030)

⁽³⁾ Electrical reject products from the same inspection lot may be used.

⁽⁴⁾ When Electrical reject products are used, the samples shall be exposed to the same thermal environments as the experience in all thermal tests required in the screening test.

⁽⁵⁾ This test shall be performed for each 3 terminals from 2 devices.

Table 2b. Group B Inspection

Gr.No	MIL-STD-750		JAXA R	100V Class			130V Class			200V Class			250V Class		
	Sub	Test Item	Method	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160
B -5a		Intermittent Operation Life	Sample Size	Level I LTPD 10											
			1042	Level II 12p											
-5b		End-Point Electrical Measurements	Conditions	Condition D, 2000 cycles ⁽¹⁾ Minimum On time: 30 seconds											
			---	Same as Gr.A-1											
B -6c		Accelerated Steady-state Gate Stress (High Temp. GS)	Sample Size	Level I LTPD 10											
			1042	Level II 12p											
-6d		End-Point Electrical Measurements	Conditions	V _{GS} =20V, T _A =150°C, 48hr or V _{GS} =20V, T _A =175°C, 24hr											
			---	Same as Gr.A-1											
-6e		Accelerated Steady-state Reverse Bias (DS)	Conditions	V _{DS} =100V V _{DS} =130V V _{DS} =200V V _{DS} =250V T _A =150°C, 240hr or T _A =175°C, 120hr											
			1042	Same as Gr.A-1											
-6f		End-Point Electrical Measurements	Conditions	Same as Gr.A-1											
			---	Same as Gr.A-1											
-6g		Bond Strength	Sample Size	20 wires											
			2037	Condition D											
B -7		Thermal impedance Z_{th(ch-c)}(ΔV_{SD})	Conditions	Gate Wire >90gf											
			3161	Source Wire >300gf >300gf >90gf >300gf >300gf >90gf >300gf >300gf >90gf >300gf >300gf >90gf											
B -7		Thermal impedance Z_{th(ch-c)}(ΔV_{SD})	Sample Size	Level I LTPD 10											
			3161	Level II 8p											
B -7		Thermal impedance Z_{th(ch-c)}(ΔV_{SD})	Conditions	T _A =25°C											
			Limits	max (°C/W) 0.5 0.83 1.67			max (°C/W) 0.5 0.83 1.67			max (°C/W) 0.5 0.83 1.67			max (°C/W) 0.5 0.83 1.67		

Note⁽¹⁾ If the samples are also used for "Intermittent operating life test" of C1-1 in the Group C inspection, the test shall be performed up to 6000 cycles.

Table 3. Group C Inspection

Gr.No	MIL-STD-750		JAXA R	100V Class			130V Class			200V Class			250V Class		
	Sub	Test Item	Method	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160
C 1-1a		Intermittent Operation Life	Sample Size	Level I LTPD 10											
			1042	Level II LTPD 10											
1-1b		End-Point Electrical Measurements	Conditions	Condition D, 6000 cycles (1) Minimum On time: 30 seconds											
			---	Same as Gr.A-1											
C 1-2a		Steady-state Bias Life test (high temp. GS applied) (2)	Sample Size	Level I LTPD 5											
			1042	Level II NA											
1-2b		End-Point Electrical Measurements	Conditions	V _{GS} =16V T _A =150°C, 1000hr											
			---	Same as Gr.A-1											
1-2c		Steady-state Bias Life test (high temp. DS applied) (2)	1042	V _{DS} =80V V _{DS} =104V V _{DS} =160V V _{DS} =200V T _A =150°C, 1000hr											
			---	Same as Gr.A-1											
1-2d		End-Point Electrical Measurements	Conditions	Same as Gr.A-1											
			---	Same as Gr.A-1											
C -2a		Temperature Cycling	Sample Size	Level I 12p											
			1051	Level II NA											
-2b		Hermetic Seal (1) Fine	Conditions	-55 ⁺⁰ ₋₅ °C ↔ 25 ⁺¹⁰ ₋₅ °C ↔ 150 ⁺⁵ ₋₀ °C 100 cycles											
			1071	Condition H											
-2c		End-Point Electrical Measurements (3)	Limits	max 1×10 ⁻³ Pa·cm ³ /s											
			1071	Condition C											
C -3		Thermal Impedance (4) (5) Z_{th(ch-o)}(ΔV_{SD})	Sample Size	Level I LTPD 10											
			3161	Level II 8p											
			Conditions	T _A =25°C											
			Limits	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67	max (°C/W) 0.5 0.83 1.67
C -4a		Safe Operating Area Test(6)	Sample Size	Level I LTPD 10											
			3474	Level II LTPD 10											
-4b		End-Point Electrical Measurements (6)	Conditions	---											
			---	Same as Gr.A-1											
C -6a		Electric Discharge Sensitivity Classification	Sample Size	Level I 3p											
			1020	Level II NA											
-6b		End-Point Electrical Measurements	Conditions	V _{GS} ±2750V ±1000V ±500V ±2750V ±1000V ±500V ±2750V ±1000V ±500V ±2750V ±1000V ±500V V _{DS} =0V											
			---	Same as Gr.A-1											

Notes(1) For the quality conformance inspection, the cycles may be reduced to 2000 cycles as a minimum.

(2) The legibility of the marking shall not apply.

(3) This test may be conducted prior to the hermetic seal.

(4) Thermal impedance curve shall be obtained during the qualification test.

(5) If the inspection lot is the one used in the Group B inspection, this test may be exempted.

(6) This test may be exempted if performed in the Group A inspection.

Table 4a. Group D Inspection

Gr.No	MIL-STD-750		JAXA R	100V Class			130V Class			200V Class			250V Class		
	Sub	Test Item	Method	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160
D	-1a	Thermal Shock (Glass Strain)	Sample Size	Level I LTPD 15 Level II LTPD 15											
			1056 Conditions	Condition B, 15 cycles											
	-1b	Temperature Cycling	1051 Conditions	-55 ⁺⁰ ₋₅ °C ↔ 25 ⁺¹⁰ ₋₅ °C ↔ 150 ⁺⁵ ₋₀ °C 45 cycles											
	-1d	Moisture Resistance	1021 Conditions	(MIL-STD-202, Method 106)											
	-1e	Hermetic Seal (1) Fine	1071 Conditions	Condition H											
			Limits	max 1×10 ⁻³ Pa·cm ³ /s											
		(2) Gross	1071 Conditions	Condition C											
	-1f	Visual Inspection	1051 1021 Conditions	---											
	-1g	End-Point Electrical Measurements	--- Conditions	Same as Gr.A-1											
D	-2a	Shock⁽¹⁾	Sample Size	Level I LTPD 15 Level II LTPD 15											
			2016 Conditions	No Operating, 14700m/s ² (1500G) 5 blows in each orientation, X ₁ , Y ₁ , Y ₂ and Z ₁											
	-2b	Vibration, Variable Frequency⁽¹⁾	2056 Conditions	100 to 2000 Hz, 4min 196 m/s ² (20G) 4 blows in each orientation X,Y,Z											
	-2c	Constant Acceleration⁽¹⁾	2006 Conditions	98100m/s ² (10000G) X ₁ , Y ₁ , Y ₂ and Z ₁ orientation											
	-2d	Hermetic Seal⁽¹⁾ (1) Fine	1071 Conditions	Condition H											
			Limits	max 1×10 ⁻³ Pa·cm ³ /s											
		(2) Gross	1071 Conditions	Condition C											
	-2e	End-Point Electrical Measurements⁽¹⁾	--- Conditions	Same as Gr.A-1											
D	-3a	Salt Atmosphere⁽²⁾	Sample Size	Level I LTPD 15 Level II LTPD 15											
			1041 Conditions	35°C, 24hr Rate of salt deposit=10 to 50g/m ² /24hr											

Notes⁽¹⁾ Samples used for subgroup 1 may be used.

⁽²⁾ Electrical reject products from the same inspection lot may be used.

Table 4b. Group D Inspection

Gr.No	MIL-STD-750		JAXA R	100V Class			130V Class			200V Class			250V Class		
	Sub	Test Item	Method	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160
D-4		Barometric Pressure (reduced)	Sample Size											Level I 3p	
			1001	Conditions	Not applicable for devices with rated voltage $\leq$ 200V.									Level II NA	
														8mmHg 60sec (minimum) $V_{DS}=250V, V_{GS}=0V$	
D-5		Internal Water Vapor (¹)	Sample Size		Level I 3p									Level II 3p	
			1018	Conditions	---										
D-6a		Resistance to Soldering Heat	Sample Size		Level I 3p									Level II NA	
			2031	Conditions	240°C, 10s										
-6b		Visual Inspection	---	Conditions	---										
-6c		Hermetic Seal (1) Fine	1071	Conditions	Condition H										
				Limits	max $1 \times 10^{-3} \text{Pa} \cdot \text{cm}^3/\text{s}$										
		(2) Gross	1071	Conditions	Condition C										
-6d		End-Point Electrical Measurements	---	Conditions	Same as Gr.A-1										

Note(¹) Electrical reject products from the same inspection lot may be used.

Table 5. Group E Inspection

Gr.No		MIL-STD-750				100V Class			130V Class			200V Class			250V Class		
	Sub	Test Item	Method	JAXA R	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160	
E -1a		Total Dose Irradiation (TID)	1019	Sample	Level I 4 p ⁽¹⁾												
				Size	Level II 4 p ⁽¹⁾												
				Conditions	Total Dose 1×10 ³ Gy(Si) Dose Rate 36Gy(Si)/h to 360Gy(Si)/h Bias Condition (during irradiation, after irradiation) (a) V _{DS} =0V , V _{GS} =20V (b) V _{DS} =0V , V _{GS} =-20V												
					(c) V _{DS} =80V, V _{GS} =0V			(c) V _{DS} =104V, V _{GS} =0V			(c) V _{DS} =160V, V _{GS} =0V			(c) V _{DS} =200V, V _{GS} =0V			
-1b End-Point Electrical Measurements					Within 24hr after irradiation												
(1)	Breakdown Voltage Drain to Source V _{DSS}	3407	Conditions	Bias Condition C I _D =1mA , V _{GS} =0V													
			Limits	min 100V DC			min 130V DC			min 200V DC			min 250V DC				
(2)	Gate-to-Source Leakage Current I _{GSS}	3411	Conditions	Bias Condition C V _{GS} =±20V , V _{DS} =0V													
			Limits	max ±100nA DC													
(3)	Drain Current I _{DSS}	3413	Conditions	Bias Condition C V _{DS} =80V , V _{GS} =0V			Bias Condition C V _{DS} =104V , V _{GS} =0V			Bias Condition C V _{DS} =160V , V _{GS} =0V			Bias Condition C V _{DS} =200V , V _{GS} =0V				
			Limits	max 10μA DC													
(4)	Gate to Source Voltage (Threshold) V _{GS(th)}	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA													
			Limits	min 1.5V DC ΔV _{GS(th)} max 2.0V													
(5)	Static Drain to Source On-State Resistance R _{DS(on)}	3421	Conditions	Pulse Test ⁽²⁾ , V _{GS} =12V													
				I _D 21A 21A 7.5A			I _D 21A 19.5A 7.5A			I _D 21A 16A 7A			I _D 21A 13A 6A				
			Limits	max (mΩ) 13 28 64			max (mΩ) 17 39 89			max (mΩ) 26 62 148			max (mΩ) 38 91 223				

Notes⁽¹⁾ This test shall be performed for each single wafer lot. When an inspection lot consists of multiple inspection sublots, one inspection subplot may be performed this test.

⁽²⁾ Pulse test: Pulse width ≤ 1ms, Duty cycle ≤ 2%

When the qualification test or the quality conformance inspection for products specified as following Table was initiated within a year from the completion date of the screening test for the inspection lot, and the device passed the test or inspection, the corresponding tests may be exempted.

Gr.No		100V Class			130V Class			200V Class			250V Class		
Sub	JAXA R	2SK 4217	2SK 4218	2SK 4219	2SK 4152	2SK 4153	2SK 4154	2SK 4155	2SK 4156	2SK 4157	2SK 4158	2SK 4159	2SK 4160
	JAXA-QTS-2030 Appendix C	Die Size 1/1 1/2 1/4			Die Size 1/1 1/2 1/4			Die Size 1/1 1/2 1/4			Die Size 1/1 1/2 1/4		
	Test Item	Package Type SMD2 SMD1 SMD0.5			Package Type SMD2 SMD1 SMD0.5			Package Type SMD2 SMD1 SMD0.5			Package Type SMD2 SMD1 SMD0.5		
	1-1a	Intermittent Operation Life											
	1-1b	End-Point Electrical Measurements											
	-3	Thermal Impedance											
	-4a	Safe Operating Area Test											
	-4b	End-Point Electrical Measurements											
D	-1a	Thermal Shock (Glass Strain)											
	-1b	Thermal Shock (Temperature Cycling)											
	-1d	Moisture Resistance											
	-1e	Hermetic Seal											
	-1f	Visual Inspection											
	-1g	End-Point Electrical Measurements											
	-2a	Shock											
	-2b	Vibration, Variable Frequency											
	-2c	Constant Acceleration											
	-2d	Hermetic Seal											
	-2e	End-Point Electrical Measurements											
	-3a	Salt Atmosphere											
	-5	Internal Water Vapor											

These tests may be exempted when the following two conditions are satisfied.													
• When the devices having the same die size or larger die size passed. • When the devices passed using the value of V_{DS} defined in paragraph 1.2 or larger value of the V_{DS}.													
This test may be exempted when the device passed the subgroup B-7 of Group B inspection.													
This test may be exempted when the device passed the subgroup A-6 of Group A inspection.													
• This test for the device having SMD-1 and SMD-0.5 Package may be exempted when the device having SMD-2 Package passed this test. • This test for the device having SMD-0.5 Package may be exempted when the device having SMD-1 Package passed this test.													
This test may be exempted when any one of the products passed the test.													

Table 7a. Qualification Test : Group A Inspection

MIL-PR F -19500N Gr.No		2030C Gr.No. (1)	MIL-STD-750			130V Class			200V Class			250V Class		
	Sub		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160
A -2	A-1	Static Characteristics (T _A =25°C)		Sample Size		116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs
	-2a	A-1a	Breakdown Voltage Drain to Source V _{DSS}	3407	Conditions	Bias Condition C I _D =1mA , V _{GS} =0V								
					Limits	min 130V DC			min 200V DC			min 250V DC		
	-2b	A-1b	Gate Current I _{GSS}	3411	Conditions	Bias Condition C V _{GS} =±20V , V _{DS} =0V								
					Limits	max ±100nA DC								
	-2c	A-1c	Drain Current I _{DSS}	3413	Conditions	Bias Condition C V _{DS} =104V , V _{GS} =0V			Bias Condition C V _{DS} =160V , V _{GS} =0V			Bias Condition C V _{DS} =200V , V _{GS} =0V		
					Limits	max 10µA DC								
	-2d	A-1d	Gate to Source Voltage (Threshold) V _{GS(th)}	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA								
					Limits	2.5 - 4.5V DC								
	-2e	A-1e	Static Drain to Source On-State Resistance R _{DS(on)}	3421	Conditions	Pulse Test ⁽²⁾ , V _{GS} =12V								
					I _D			I _D			I _D			
					21A 19.5A 7.5A	21A 16A 7A	21A 13A 6A							
	-2f	A-1f	Forward Transconductance g _{fs}	3475	Conditions	Pulse Test ⁽²⁾ , V _{DS} =25V								
					I _D			I _D			I _D			
21A 19.5A 7.5A					21A 16A 7A	21A 13A 6A								
-2g	A-1g	Forward Voltage V _{SD}	---	Conditions	Pulse Test ⁽²⁾ , V _{GS} =0V									
				I _D			I _D			I _D				
				42A 39A 15A	42A 32A 14A	42A 26A 12A								
				Limits	max 1.6VDC			max 1.6VDC			max 1.6VDC			
A -3	A-2	Static Characteristics (T _A =-55, 125°C)		Sample Size		116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs
	-3a	A-3a	Gate to Source Voltage (Threshold) V _{GS(th)} (-55°C)	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA								
					Limits	max 5.0V DC								
	-3b	A-3b	Forward Transconductance g _{fs} (-55°C)	3475	Conditions	Pulse Test ⁽²⁾ , V _{DS} =25V								
					I _D			I _D			I _D			
					21A 19.5A 7.5A	21A 16A 7A	21A 13A 6A							
	-3c	A-2a	Gate Current I _{GSS} (125°C)	3411	Conditions	Bias Condition C V _{GS} =±20V , V _{DS} =0V								
					Limits	max ±100nA DC								
	-3d	A-2b	Drain Current I _{DSS} (125°C)	3413	Conditions	Bias Condition C V _{DS} =104V , V _{GS} =0V			Bias Condition C V _{DS} =160V , V _{GS} =0V			Bias Condition C V _{DS} =200V , V _{GS} =0V		
					Limits	max 25µA DC								
	-3e	A-2c	Gate to Source Voltage (Threshold) V _{GS(th)} (125°C)	3404	Conditions	Bias Condition C V _{GS} =V _{DS} , I _D =1mA								
					Limits	min 1.5V DC								
	-3f	A-2d	Static Drain to Source On-State Resistance R _{DS(on)} (125°C)	3421	Conditions	Pulse Test ⁽²⁾ , V _{GS} =12V								
					I _D			I _D			I _D			
21A 19.5A 7.5A					21A 16A 7A	21A 13A 6A								
				Limits	max			max			max			
				31mΩ 71mΩ 162mΩ	52mΩ 125mΩ 297mΩ	76mΩ 183mΩ 448mΩ								

Notes⁽¹⁾ The symbols refer to the test method number in JAXA-QTS-2030C.

⁽²⁾ Pulse width $\leq 1\text{ms}$, Duty cycle $\leq 2\%$

Table 7b. Qualification Test : Group A Inspection

MIL-PRF-19500N Gr.No	2030C Gr.No.	MIL-STD-750			130V Class			200V Class			250V Class					
		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160			
A -4	A-4	Dynamic Characteristics (T _A =25°C)			Sample Size	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs	116pcs		
		Switching Time Test (1) Turn-on t _{d(on)} Rise time: t _r (2) Turn-off t _{d(off)} Fall time: t _f		3472	Conditions	V _{DD} =65V V _{GS} =12V , R _g =10Ω			V _{DD} =100V V _{GS} =12V , R _g =10Ω			V _{DD} =125V V _{GS} =12V , R _g =10Ω				
						I _D			I _D			I _D				
						42A	39A	15A	42A	32A	14A	42A	26A	12A		
				Limits	max			max			max					
				t _{d(on)}	65ns	40ns	30ns	65ns	40ns	30ns	65ns	40ns	30ns			
				t _r	30ns	20ns	20ns	30ns	20ns	20ns	30ns	20ns	20ns			
				t _{d(off)}	190ns	100ns	65ns	190ns	100ns	65ns	190ns	100ns	65ns			
				t _f	65ns	30ns	15ns	35ns	20ns	15ns	30ns	15ns	10ns			
A -5a	A-6a	Safe Operating Area test		Sample Size	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs			
					3474	Conditions	---			---			---			
	-5b	A-6b	End-Point Electrical Measurements	---		Same as Gr.A-2										
A -7	A-7	Dynamic Characteristics (T _A =25°C)			Sample Size	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs		
		A-7a	Gate Charge (1) Q _g (2) Q _{gd} (3) Q _{gs}	3471	Conditions	V _{GS} =12V V _{DS} =65V			V _{GS} =12V V _{DS} =100V			V _{GS} =12V V _{DS} =125V				
						I _D			I _D			I _D				
						42A	39A	15A	42A	32A	14A	42A	26A	12A		
						Limits	max			max			max			
						Q _g	220nC	100nC	50nC	220nC	100nC	50nC	220nC	100nC	50nC	
						Q _{gd}	70nC	30nC	10nC	70nC	30nC	10nC	70nC	30nC	10nC	
	Q _{gs}	60nC	30nC	13nC	60nC	30nC	13nC	60nC	30nC	13nC						
	-7b	A-7b	Reverse Recovery Characteristics (1) t _{rr} (2) Q _{rr}		3473	Conditions	I _F = I _D			I _F = I _D			I _F = I _D			
							42A	39A	15A	42A	32A	14A	42A	26A	12A	
							V _{GS} =0V -di/dt=100A/μs									
							Limits	max			max			max		
							t _{rr}	765ns	750ns	525ns	1050ns	1200ns	950ns	1500ns	1350ns	950ns
							Q _{rr}	13.0μC	12.0μC	6.5μC	20.0μC	18.0μC	9.0μC	29.0μC	18.0μC	10.0μC

Table 8a. Qualification Test : Group B Inspection

MIL-PR F -19500N Gr.No	2030C Gr.No	MIL-STD-750			130V Class			200V Class			250V Class		
		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160
B-1	B-1	External Dimensions ⁽¹⁾	Sample Size	---	---	---	---	22pcs	22pcs	22pcs	---	---	---
			2066	Conditions	Omitted (Tested in 200V class because of the same package.)			---			Omitted (Tested in 200V class because of the same package.)		
B-2a	B-4	Solderability ⁽¹⁾ ⁽²⁾	Sample Size	15pcs	15pcs	15pcs	---	---	---	---	---	---	---
			2026	Conditions	---			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		
-2b	B-2	Resistance to Solvents ⁽¹⁾ ⁽²⁾	1022	Conditions	---			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		
B-3b	B-3b	Temperature Cycling (Air to Air)	Sample Size	---	---	---	---	22pcs	22pcs	22pcs	---	---	---
			1051	Conditions	Omitted (Tested in 200V class because of the same package.)			-55 ⁺⁰ ₋₅ °C ↔ 25 ⁺¹⁰ ₋₅ °C ↔ 150 ⁺⁵ ₋₀ °C 100 cycles			Omitted (Tested in 200V class because of the same package.)		
-3c	B-3c	Surge Test (1) Gate Shock (2) Avalanche	4066	Conditions	Omitted (Tested in 200V class because of the same package.)			V _{GS} =35V			Omitted (Tested in 200V class because of the same package.)		
			4066	Conditions	Omitted (Tested in 200V class because of the same package.)			V _{DS} =100V I _{D(pulse)} 42A 32A 14A L=100μH, R _g =10Ω			Omitted (Tested in 200V class because of the same package.)		
-3d	B-3d	Hermetic Seal (1) Fine (2) Gross	1071	Conditions	Omitted (Tested in 200V class because of the same package.)			Condition H			Omitted (Tested in 200V class because of the same package.)		
				Limits	max 1×10 ⁻³ Pa·cm ³ /s								
-3e	B-3e	End-Point Electrical Measurements	---	Conditions	Omitted (Tested in 200V class because of the same package.)			Same as Gr.A-2			Omitted (Tested in 200V class because of the same package.)		
			2075 2071	Conditions	Omitted (Tested in 200V class because of the same package.)			---			Omitted (Tested in 200V class because of the same package.)		
-3g	B-3g	Bond Strength	2037	Conditions	Omitted (Tested in 200V class because of the same package.)			Condition D			Omitted (Tested in 200V class because of the same package.)		
				Limits	Gate Wire >90gf Source Wire >300gf >300gf >90gf			>300gf >300gf >90gf			>300gf >300gf >90gf		
-3h	B-3h	SEM	2077	Conditions	After bond strength test								
-3i	B-3i	Die Shear	2017	Conditions	Omitted (Tested in 200V class because of the same package.)			---			Omitted (Tested in 200V class because of the same package.)		
				Limits	min 2.5kgf								

Notes ⁽¹⁾ Electrical reject products from the same inspection lot may be used.

⁽²⁾ When electrical reject products are used, the samples shall be exposed to the same thermal environments as the experience in all thermal tests required in the screening test.

Table 8b. Qualification Test : Group B Inspection

MIL-PR F -19500N Gr.No	2030C Gr.No.	MIL-STD-750			130V Class			200V Class			250V Class			
		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160	
B -4a	B-5a	Intermittent Operation Life		Sample Size	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	
			1042	Conditions	Condition D, 2000 cycles Refer to the result of Gr.C-6.									
	-4b	B-5b	End-Point Electrical Measurements	---	Conditions	Refer to the result of Gr.C-6.								
B -5a	B-6c	Steady-state Gate Stress (High temp. GS)		Sample Size	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	
			1042	Conditions	V _{GS} =20V T _A =150°C , 48hr									
	-5b	B-6d	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-2								
	-5c	B-6e	Accelerated Steady-state Reverse Bias (High temp. DS)	1042	Conditions	V _{DS} =130V			V _{DS} =200V T _A =150°C, 240hr			V _{DS} =250V		
	-5d	B-6f	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-2								
	-5e	B-6g	Bond Strength	2037	Conditions	Condition D								
					Gate Wire >90gf									
Limits				Source Wire >300gf >300gf >90gf >300gf >300gf >90gf >300gf >300gf >90gf										
B -6	B-7	Thermal Impedance Z _{th(ch-c)} (ΔV _{SD})	3161	Sample Size	22pcs	22pcs	22pcs	22pcs	22pcs	22pcs	22pcs	22pcs	22pcs	
				Conditions	T _A =25°C									
				Limits	max 0.5°C/W 0.83°C/W 1.67°C/W			max 0.5°C/W 0.83°C/W 1.67°C/W			max 0.5°C/W 0.83°C/W 1.67°C/W			

Table 9a. Qualification Test : Group C Inspection

MIL-PR F -19500N Gr.No	2030C Gr.No.	MIL-STD-750			130V Class			200V Class			250V Class		
Sub		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160
C -1	B-1	External Dimensions⁽¹⁾		Sample Size	---	---	---	---	---	---	---	---	---
			2066	Conditions	Performed in Gr.B-1 test.								
C -2a	D-1a	Thermal Shock (Glass Strain)		Sample Size	---	---	---	---	---	---	22pcs	22pcs	22pcs
			1056	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition B, 25 cycles		
-2b	D-1b	Temperature Cycling	1051	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			-55 ⁺⁰ .5°C↔25 ⁺¹⁰ .5°C↔150 ⁺⁵ .0°C 45 cycles		
-2d	D-1d	Moisture Resistance	1021	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			(MIL-STD-202 Method 106)		
-2e	D-1e	Hermetic Seal (1) Fine	1071	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition H		
				Limits							max 1×10 ⁻³ Pa-cm ³ /s		
		(2) Gross	1071	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition C		
-2f	D-1g	End-Point Electrical Measurements	---	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Same as Gr.A-2		
C -3a	D-2a	Shock		Sample Size	22pcs	22pcs	22pcs	---	---	---	---	---	---
			2016	Conditions	No Operating, 14710m/s ² (1500G) X ₁ , Y ₁ , Y ₂ , Z ₁ orientation 5 blows			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		
-3b	D-2b	Vibration, Variable Frequency	2056	Conditions	100 to 2000 Hz 196.1 m/s ² (20G)			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		
-3c	D-2c	Constant Acceleration	2006	Conditions	98066.5m/s ² (10000G) X ₁ , Y ₁ , Y ₂ , Z ₁ orientation			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		
-3d	D-2f	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-2			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		

Note⁽¹⁾ Electrical reject products from the same inspection lot may be used.

Table 9b. Qualification Test : Group C Inspection

MIL-PRF-19500N Gr.No	2030C Gr.No.	MIL-STD-750			130V Class			200V Class			250V Class		
		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160
C -4	D-3a	Salt Atmosphere (¹)		Sample Size	15pcs	15pcs	15pcs	---	---	---	---	---	---
			1041	Conditions	35°C, 24hr Rate of salt deposit = 10 to 50g/m ² /24hr			Omitted (Tested in 130V class because of the same package.)			Omitted (Tested in 130V class because of the same package.)		
C -5	C-3	Thermal Impedance $Z_{th(ch-c)}(\Delta V_{SD})$		Sample Size	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs
			3161	Conditions	Performed in Gr.B-6 test.								
C -6a	C1-1a	Intermittent Operation Life		Sample Size	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs	8pcs
			1042	Conditions	Condition D, 6000 cycles								
-6b	C1-1b	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-2								
C -7	D-5	Internal Water Vapor		Sample Size	---	---	---	---	---	---	3pcs	3pcs	3pcs
			1018	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			---		

Note (¹) Electrical reject products from the same inspection lot may be used.

MIL-PR F -19500N Gr.No		2030C Gr.No.	MIL-STD-750			130V Class			200V Class			250V Class		
	Sub		Test Item	Method	JAXA R	2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160
D -2	E-1a	Total Dose Irradiation (TID)		Sample Size		---	---	---	---	---	---	4/4/4pcs	---	---
			1019	Conditions		Tested in 2SK4158.	Tested in 2SK4158.	Total Dose 1×10 ³ Gy(Si) Dose Rate 1×10 ³ Gy(Si)/h Bias Condition (during irradiation, after irradiation) (a)V _{DS} =0V , V _{GS} =20V (b)V _{DS} =0V , V _{GS} =-20V (c)V _{DS} =200V , V _{GS} =0V						
-2a	E-1b	End-Point Electrical Measurements	---									Within 24hr after irradiation		
(1)		Breakdown Voltage Drain to Source V _{DSS}	3407	Conditions		Tested in 2SK4158.	Tested in 2SK4158.	Bias Condition C I _D =1mA , V _{GS} =0V						
				Limits		min 250V DC	---	---						
(2)		Gate Current I _{GSS}	3411	Conditions		Tested in 2SK4158.	Tested in 2SK4158.	Bias Condition C V _{GS} =±20V , V _{DS} =0V						
				Limits		max ±100nA DC	---	---						
(3)		Drain Current I _{DSS}	3413	Conditions		Tested in 2SK4158.	Tested in 2SK4158.	Bias Condition C V _{DS} =200V , V _{GS} =0V						
				Limits		max 10μA DC	---	---						
(4)		Gate to Source Voltage (Threshold) V _{GS(th)}	3404	Conditions		Tested in 2SK4158.	Tested in 2SK4158.	Bias Condition C V _{GS} =V _{DS} , I _D =1mA						
				Limits		min 1.5V DC ΔV _{GS(th)} max 2.0V	---	---						
(5)		Static Drain to Source On-State Resistance R _{DS(on)}	3421	Conditions		Tested in 2SK4158.	Tested in 2SK4158.	Pulse Test ⁽¹⁾ , V _{GS} =12V I _D =42A						
				Limits		max 38mΩ	---	---						

Note⁽¹⁾ Pulse width $\leq 1\text{ms}$, Duty cycle $\leq 2\%$

Table 11a. Qualification Test : Group E Inspection

MIL-PRF-19500N Gr.No	2030C Gr.No.	MIL-STD-750		JAXA R	130V Class			200V Class			250V Class			
		Test Item	Method		2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160	
E-1a	C-2a	Temperature Cycling		Sample Size	---	---	---	---	---	---	45pcs	45pcs	45pcs	
			1051	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			-55 ^{+0.5} °C↔25 ^{+10.5} °C↔150 ^{+5.0} °C 500 cycles			
	-1b	C-2b	Hermetic Seal (1) Fine	1071	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition H		
					Limits							max 1×10 ⁻³ Pa-cm³/s		
		(2) Gross	1071	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition C			
-1c	C-2c	End-Point Electrical Measurements ⁽¹⁾	---	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Same as Gr.A-2			
E-2a	C1-2a	Steady-state Bias Life test (High Temperature GS Applied) ⁽²⁾		Sample Size	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	15pcs	
			1042	Conditions	V _{GS} =16V T _A =150°C , 1000hr									
	-2b	C1-2b	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-2								
	-2c	C1-2c	Steady-state Bias Life test (High Temperature DS Applied) ⁽²⁾	1042	Conditions	V _{DS} =104V			V _{DS} =160V T _A =150°C , 1000hr			V _{DS} =200V		
-2d	C1-2d	End-Point Electrical Measurements	---	Conditions	Same as Gr.A-2									
E-4	C-3	Thermal Impedance ⁽³⁾		Sample Size	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	
			3161	Conditions	T _A =25°C									
			Limits	max 0.5°C/W			max 0.83°C/W			max 1.67°C/W				
E-5	D-4	Barometric Pressure		Sample Size	---	---	---	---	---	---	3pcs	3pcs	3pcs	
			1001	Conditions	Not applied for the devices with rated voltage ≤ 200V ⁽⁴⁾			Not applied for the devices with rated voltage ≤ 200V ⁽⁴⁾			8mmHg 60sec (minimum) V _{DS} =250V, V _{GS} =0V			
E-6a	C-6a	Electric Discharge Sensitivity Classification		Sample Size	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	3pcs	
			1020	Conditions	V _{GS} ±2750V ±1000V ±500V			V _{GS} ±2750V ±1000V ±500V			V _{GS} ±2750V ±1000V ±500V			
	-6b	C-6b	End-Point Electrical Measurements	---	Conditions	V _{DS} =0V Same as Gr.A-2								

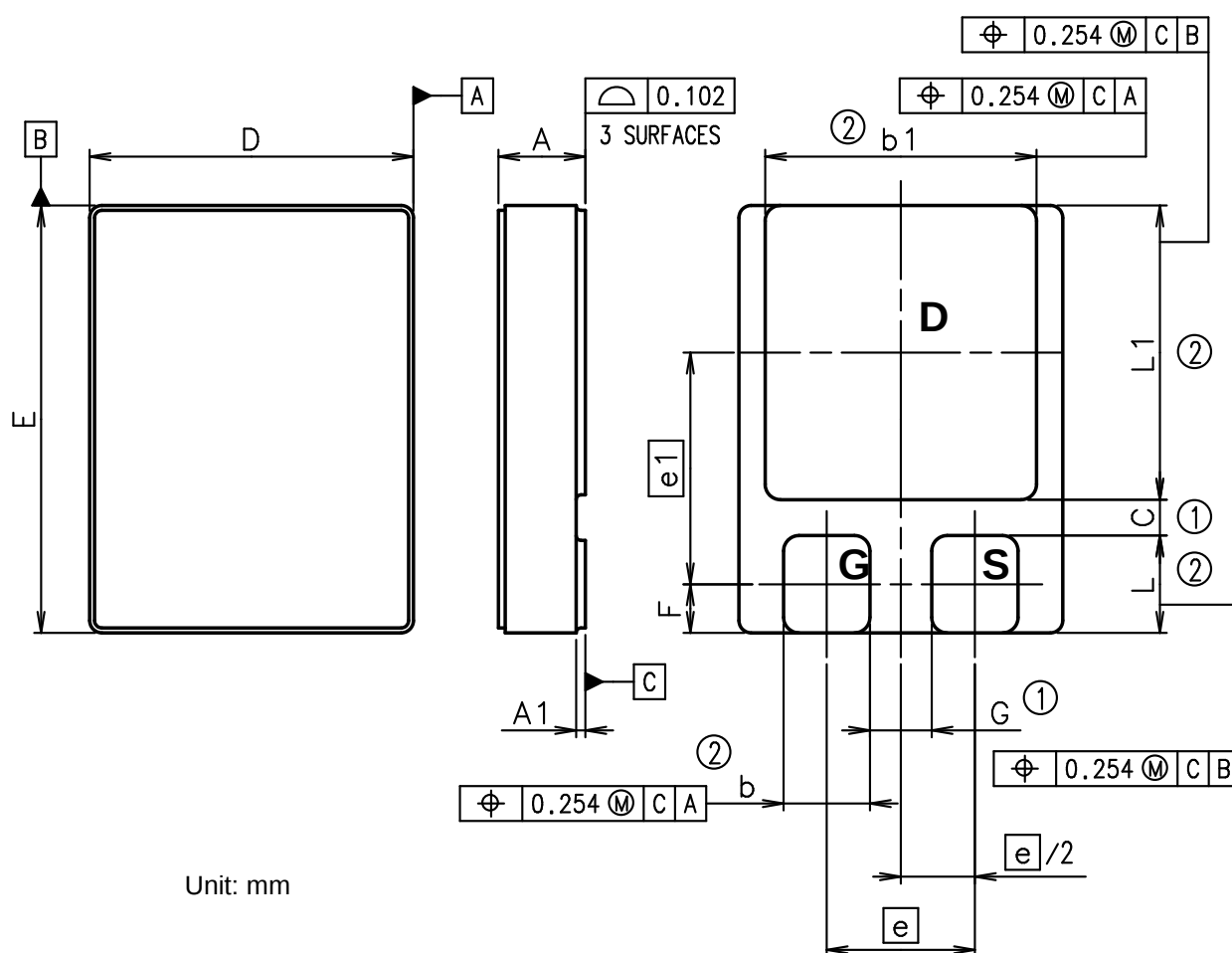
Notes ⁽¹⁾ This test may be conducted prior to the hermetic seal.⁽²⁾ The legibility of the marking shall not apply.⁽³⁾ Thermal impedance curve shall be obtained during the qualification test.⁽⁴⁾ See Table C-4 in JAXA-QTS-2030C Appendix C.

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Table 11b. Qualification Test : Group E Inspection															
MIL-PRF-19500N Gr.No	2030C Gr.No.	MIL-STD-750		JAXA R	130V Class			200V Class			250V Class				
		Test Item	Method		2SK4152	2SK4153	2SK4154	2SK4155	2SK4156	2SK4157	2SK4158	2SK4159	2SK4160		
E-7a	D-6a	Resistance to Soldering Heat		Sample Size	---	---	---	---	---	---	3pcs	3pcs	3pcs		
			2031	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			240°C, 10s				
-7b	D-6c	Hermetic Seal (1) Fine	1071	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition H				
				Limits							max 1×10 ⁻³ Pa-cm³/s				
-7c	D-6d	End-Point Electrical Measurements ⁽¹⁾	---	Conditions	Omitted (Tested in 250V class because of the same package.)			Omitted (Tested in 250V class because of the same package.)			Condition C				
				Limits							Same as Gr.A-2				
E-8	E-2, 3	Radiation Hardness (SEB/SEGR test)	1080	Sample Size	3pcs			3pcs			3pcs				
				Conditions	Ion: ⁸⁹ Y Energy: 928MeV										
					LET: 38.4MeV/(mg/cm²) ⁽²⁾			LET: 39.3MeV/(mg/cm²) ⁽²⁾			LET: 40.1MeV/(mg/cm²) ⁽²⁾				
					Range (Si): 102µm T _A =25+/-5°C Fluence: 3E5+/-5% ions/cm²										
					V _{DS} =130V and V _{GS} =-7.5V			V _{DS} =200V and V _{GS} =-7.5V			V _{DS} =250V and V _{GS} =-7.5V				
E-8	E-2, 3	Radiation Hardness (SEB/SEGR test)	1080	Limits	I _{GSS} ≤10µA and shall not be destroyed										

Notes⁽²⁾ This test may be conducted prior to the hermetic seal.
⁽²⁾ Average LET in the device.

Notes⁽¹⁾ This test may be conducted prior to the hermetic seal.

⁽²⁾ Average LET in the device.



Symbol	Dimension (mm)		
	Min	Typ	Max
A	—	—	3.58
A1	0.254	0.381	0.508
b	3.43	3.555	3.68
b1	11.05	11.175	11.30
C	0.89	—	—
D	13.21	13.335	13.46
E	17.40	17.525	17.65

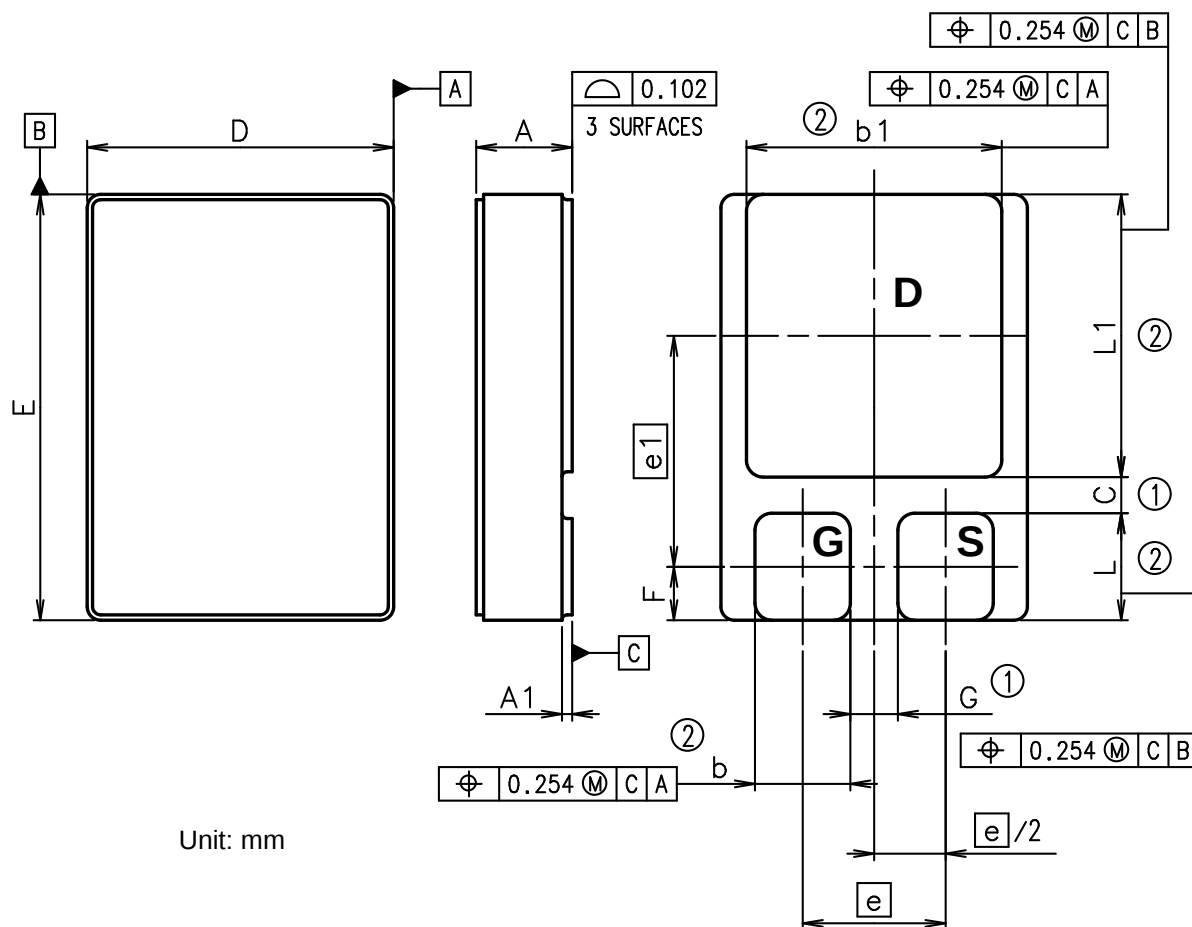
Symbol	Dimension (mm)		
	Min	Typ	Max
$e/2$	—	3.05	—
e	—	6.10	—
$e1$	—	9.50	—
F	—	1.99	—
G	1.27	—	—
L	3.87	3.99	4.11
L1	11.94	12.065	12.19

Notes: ① Dimension includes metallization flash.

② Dimension does not include metallization flash.

Note: All terminals are isolated from the case.

**Figure 1a. Package Configuration and Terminal Connection of SMD-2 type package
(JAXA R 2SK4152, 2SK4155, 2SK4158, 2SK4217)**



Symbol	Dimension (mm)		
	Min	Typ	Max
A	—	—	3.58
A1	0.254	0.381	0.508
b	3.43	3.555	3.68
b1	9.40	9.525	9.65
C	0.76	—	—
D	11.31	11.43	11.55
E	15.75	15.875	16.00

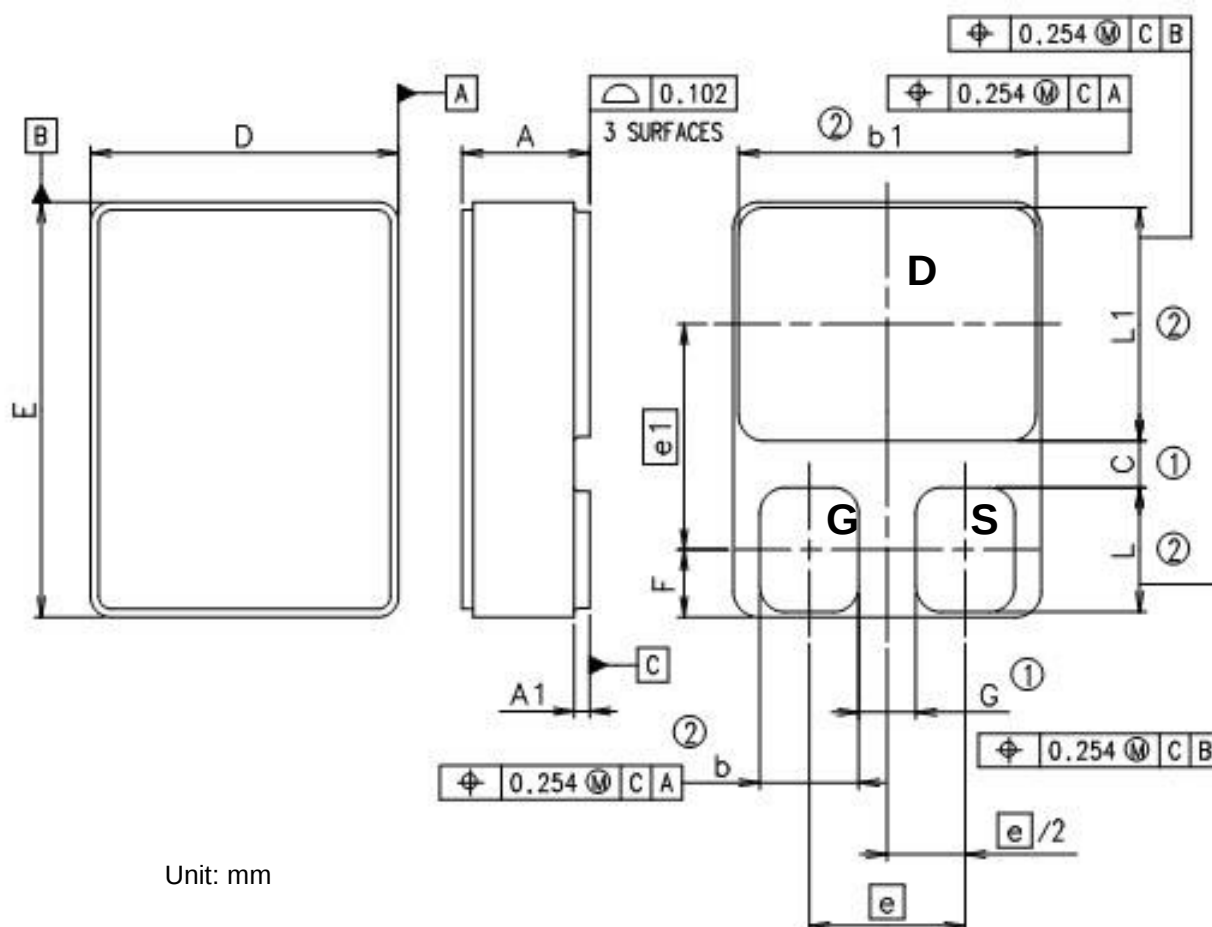
Symbol	Dimension (mm)		
	Min	Typ	Max
e/2	—	2.67	—
e	—	5.33	—
e1	—	8.61	—
F	—	1.99	—
G	0.89	—	—
L	3.87	3.99	4.11
L1	10.42	10.54	10.66

Notes: ① Dimension includes metallization flash.

② Dimension does not include metallization flash.

Note: All terminals are isolated from the case.

Figure 1b. Package Configuration and Terminal Connection of SMD-1 type package (JAXA R 2SK4153, 2SK4156, 2SK4159, 2SK4218)



Unit: mm

Symbol	Dimension (mm)		
	Min	Typ	Max
A	—	—	3.12
A1	0.254	0.381	0.508
b	2.29	2.415	2.54
b1	7.14	7.265	7.39
C	0.76	—	—
D	7.40	7.52	7.64
E	10.04	10.16	10.28

Symbol	Dimension (mm)		
	Min	Typ	Max
$\frac{e}{2}$	—	1.905	—
e	—	3.81	—
e1	—	5.52	—
F	—	1.65	—
G	0.762	—	—
L	2.93	3.05	3.17
L1	5.59	5.715	5.84

Notes: ① Dimension includes metallization flash.

② Dimension does not include metallization flash.

Note: All terminals are isolated from the case.

**Figure 1c. Package Configuration and Terminal Connection of SMD-0.5 type package
(JAXA R 2SK4154, 2SK4157, 2SK4160, 2SK4219)**

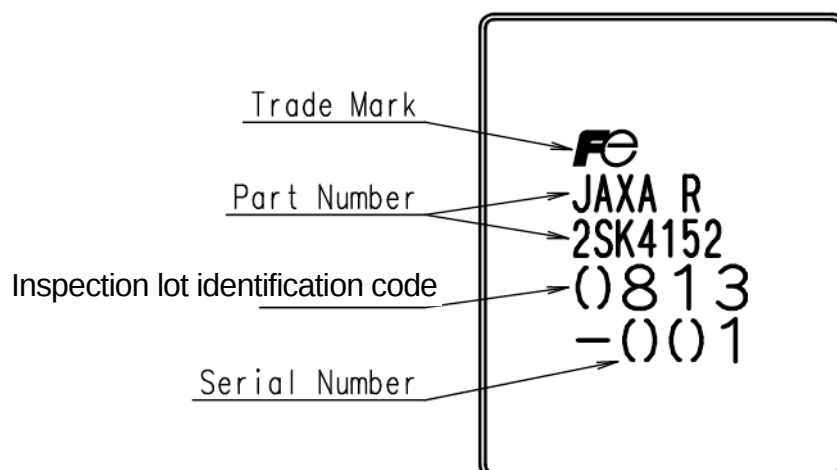


Fig. 2a Marking (SMD-2)
(JAXA R 2SK4152, 2SK4155, 2SK4158, 2SK4217)

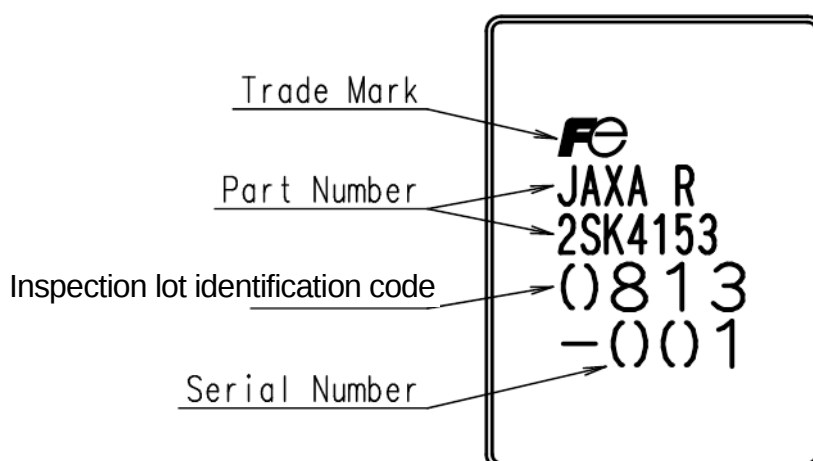


Fig. 2b Marking (SMD-1)
(JAXA R 2SK4153, 2SK4156, 2SK4159, 2SK4218)

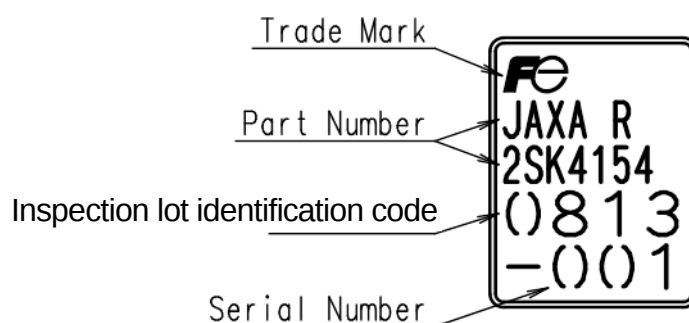


Figure 2c. Marking (SMD-0.5)
(JAXA R 2SK4154, 2SK4157, 2SK4160, 2SK4219)

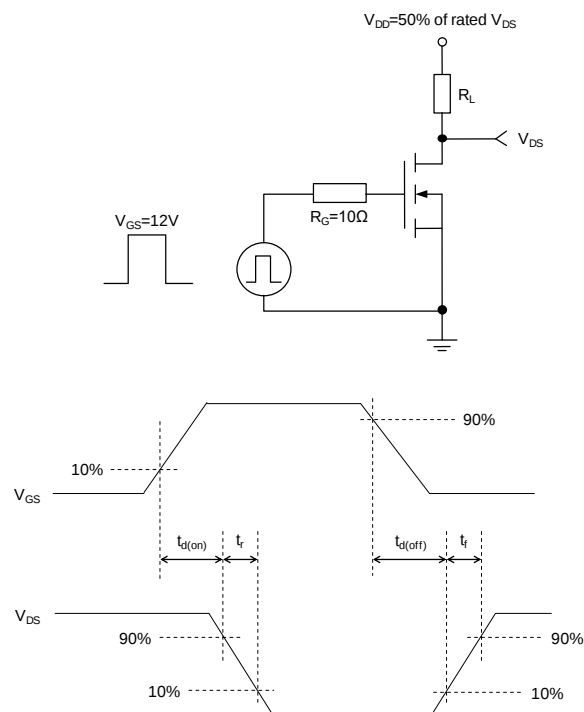


Figure 3. Switching time test circuit and waveforms

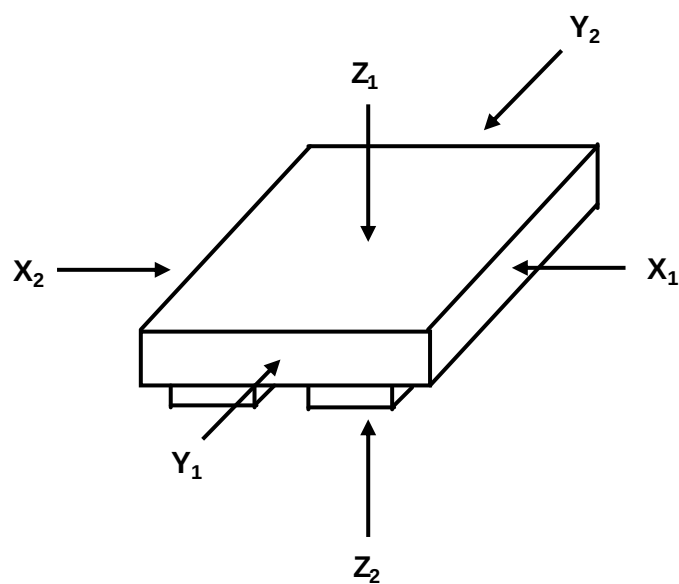


Figure 4. Orientation

JAXA R 2SK4152

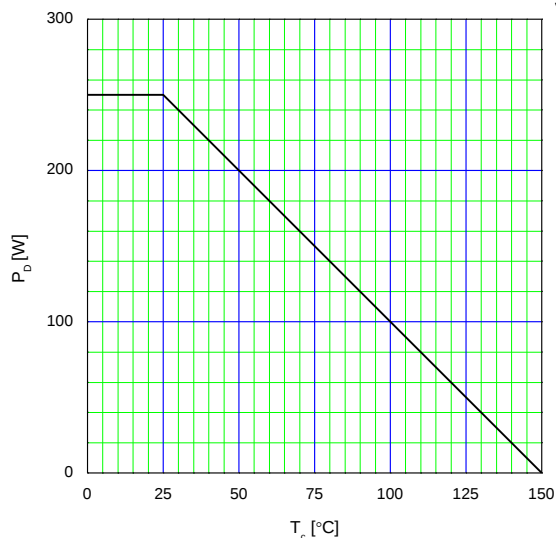


Fig. 5 Allowable Power Dissipation
 $P_D = f(T_c)$

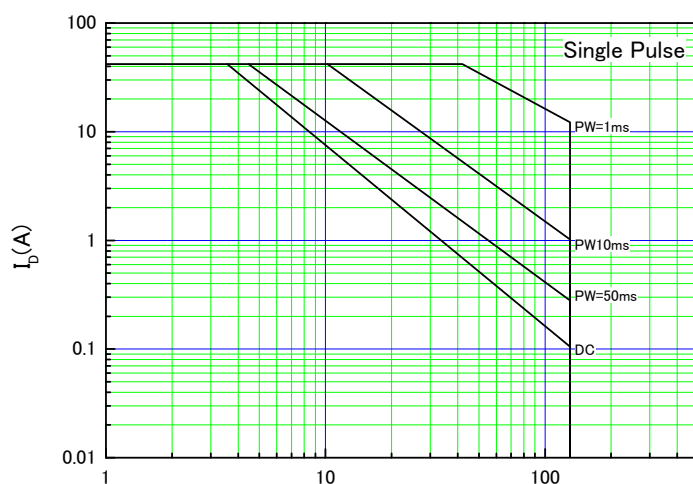


Fig. 6 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4153

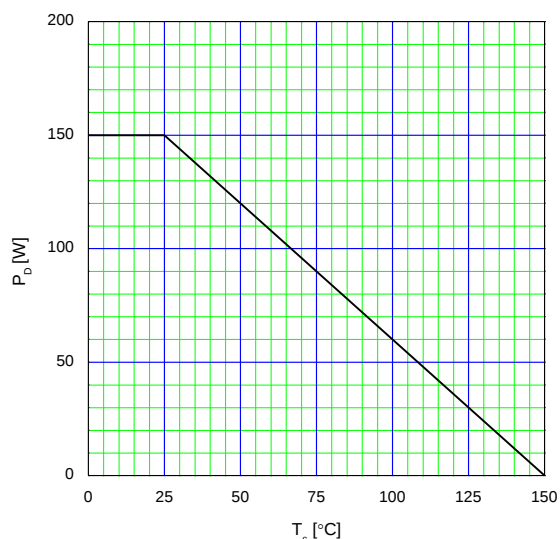


Fig. 7 Allowable Power Dissipation
 $P_D = f(T_c)$

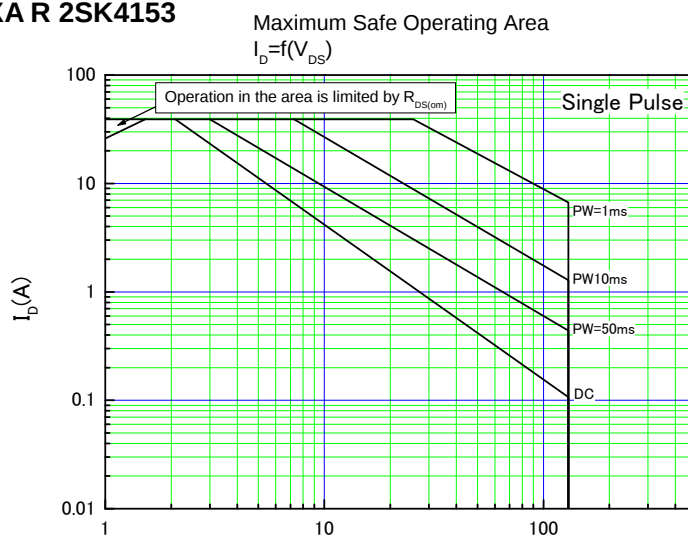


Fig. 8 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4154

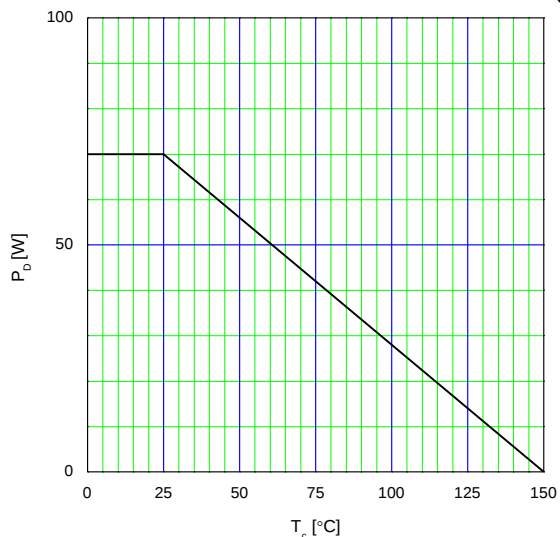


Fig. 9 Allowable Power Dissipation
 $P_D = f(T_c)$

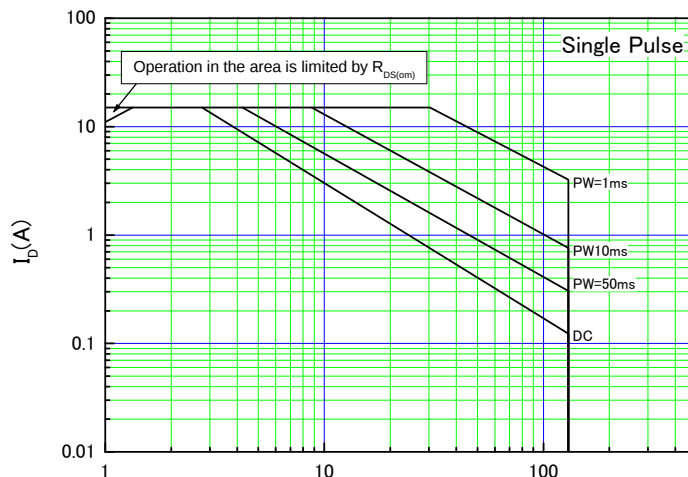


Fig. 10 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4155

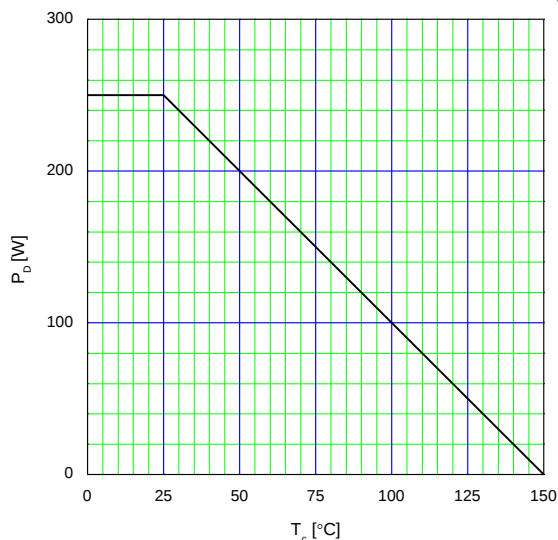


Fig. 11 Allowable Power Dissipation
 $P_D = f(T_c)$

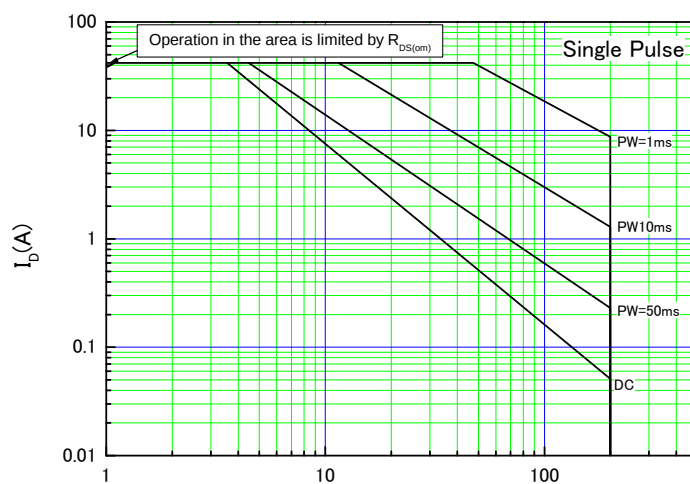


Fig. 12 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4156

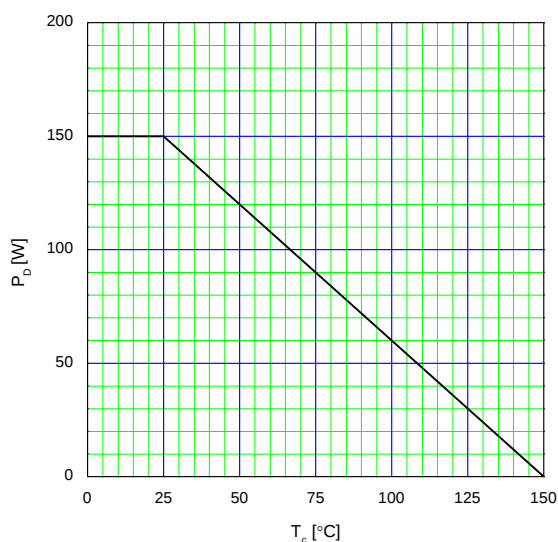


Fig. 13 Allowable Power Dissipation
 $P_D = f(T_c)$

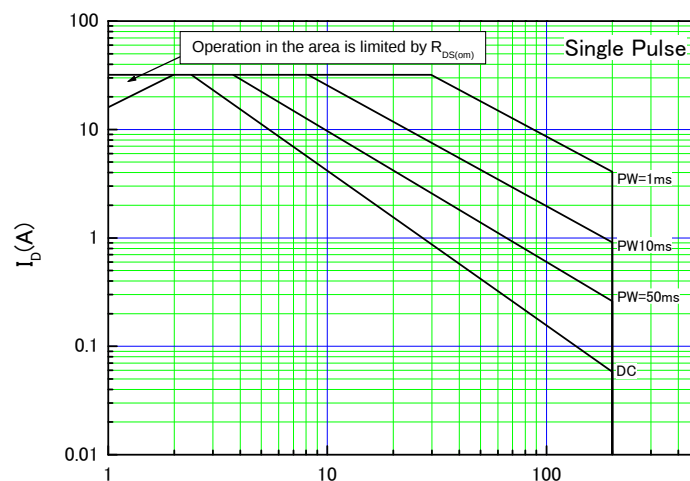


Fig. 14 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4157

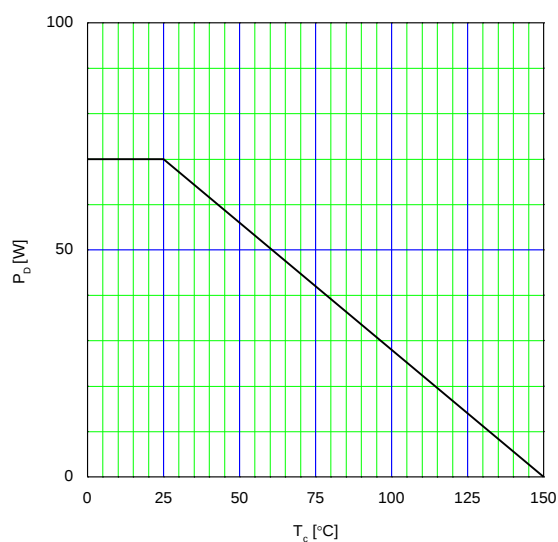


Fig. 15 Allowable Power Dissipation
 $P_D = f(T_c)$

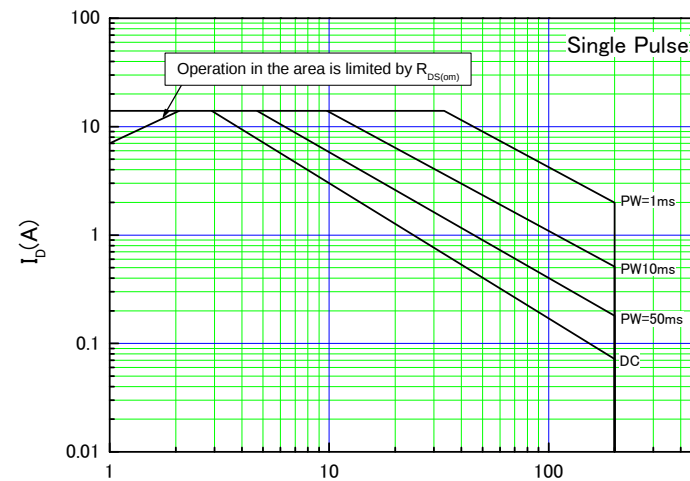


Fig. 16 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4158

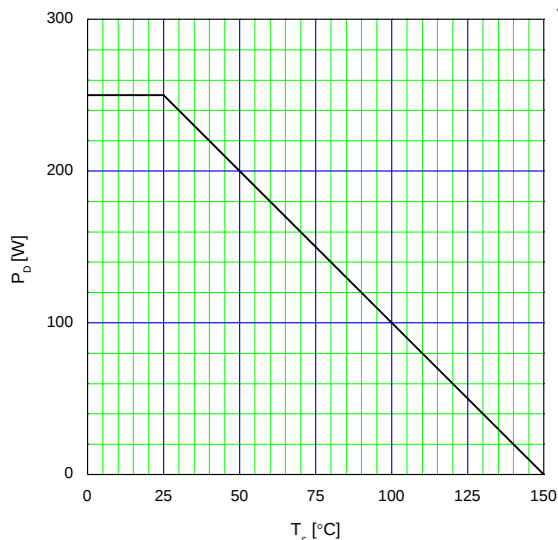


Fig. 17 Allowable Power Dissipation
 $P_D = f(T_c)$

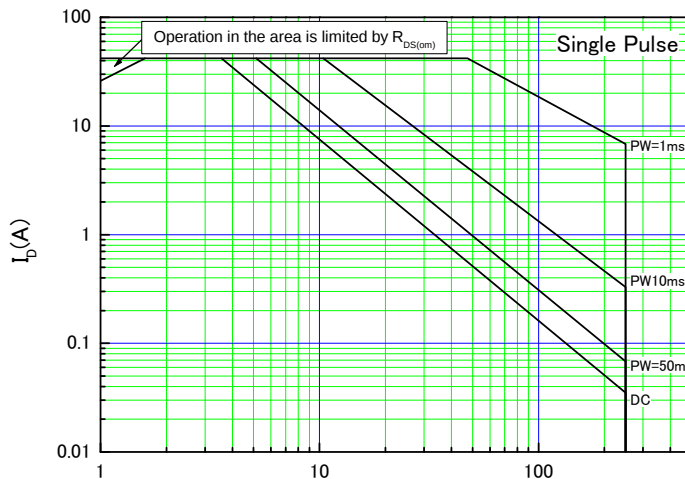


Fig. 18 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4159

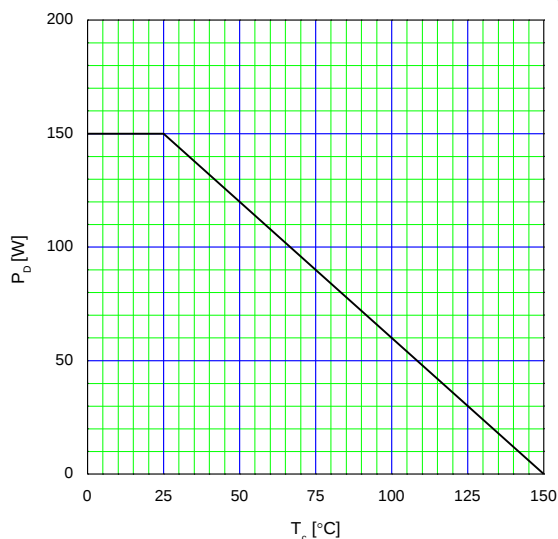


Fig. 19 Allowable Power Dissipation
 $P_D = f(T_c)$

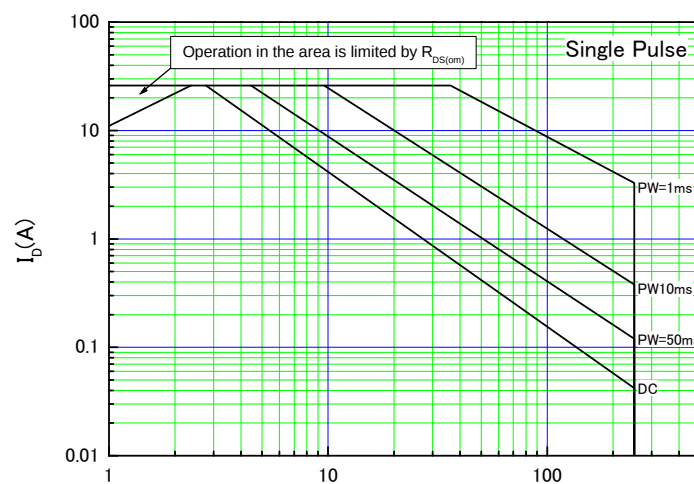


Fig. 20 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4160

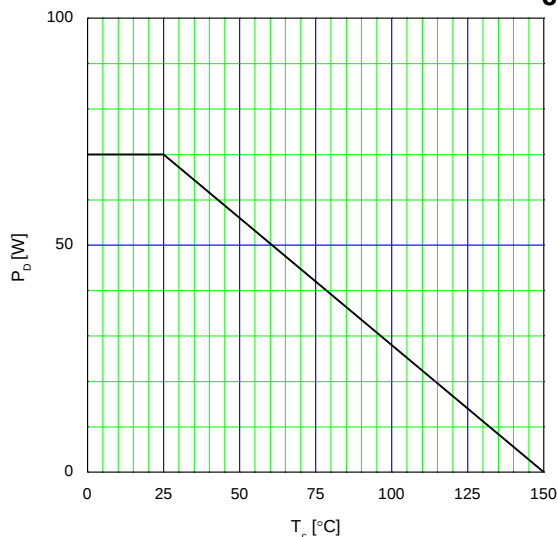


Fig. 21 Allowable Power Dissipation
 $P_D = f(T_c)$

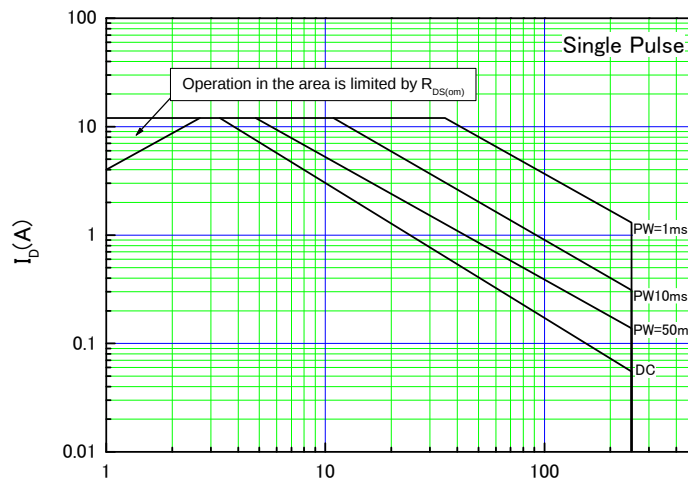


Fig. 22 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4217

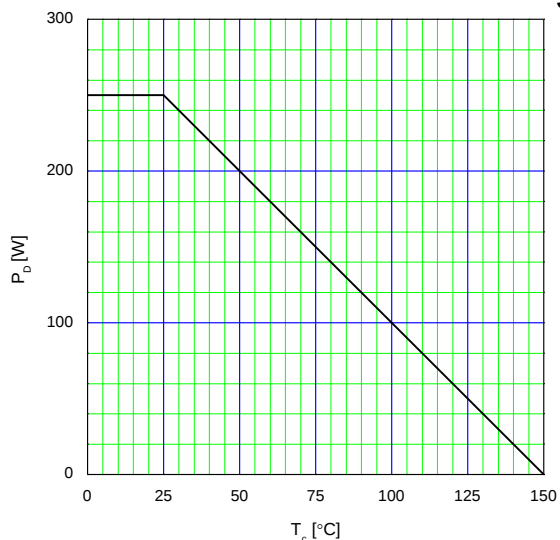


Fig. 23 Allowable Power Dissipation
 $P_D = f(T_c)$

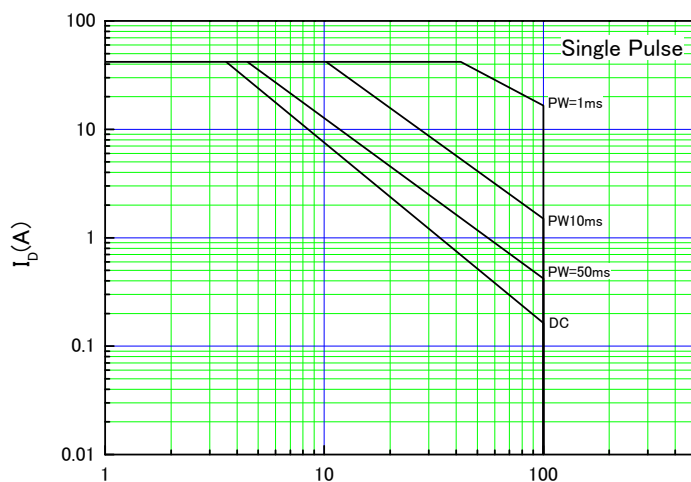


Fig. 24 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4218

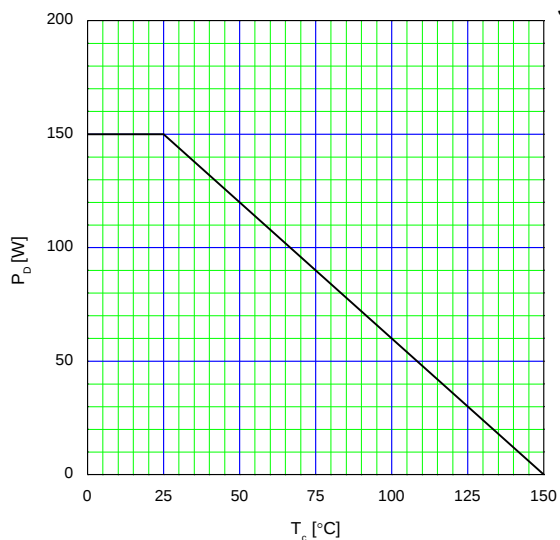


Fig. 25 Allowable Power Dissipation
 $P_D = f(T_c)$

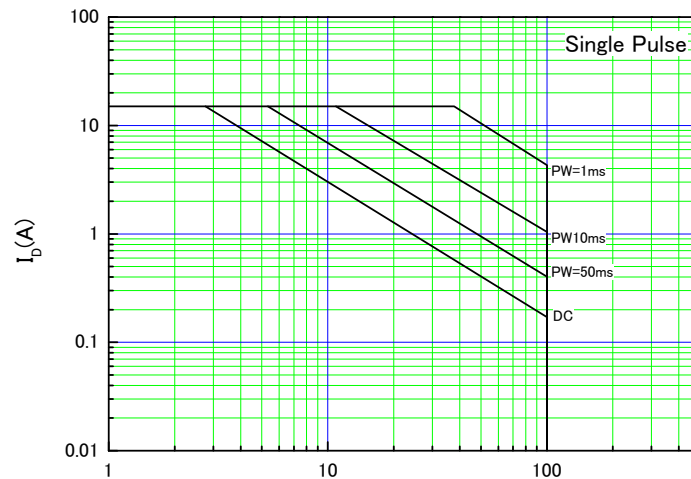


Fig. 26 Maximum Safe Operating Area $I_D = f(V_{DS})$

JAXA R 2SK4219

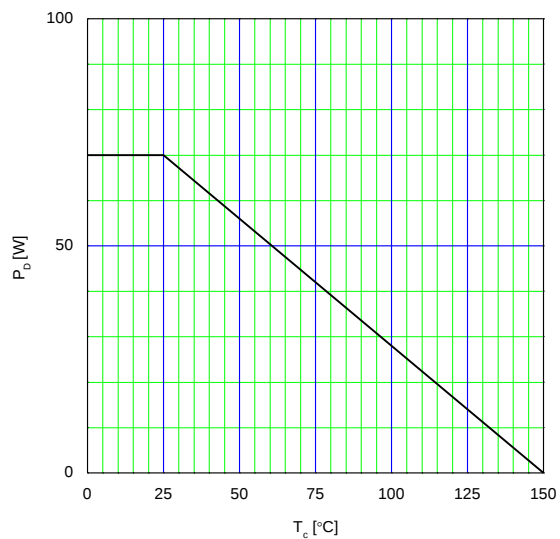


Fig. 27 Allowable Power Dissipation
 $P_D = f(T_c)$

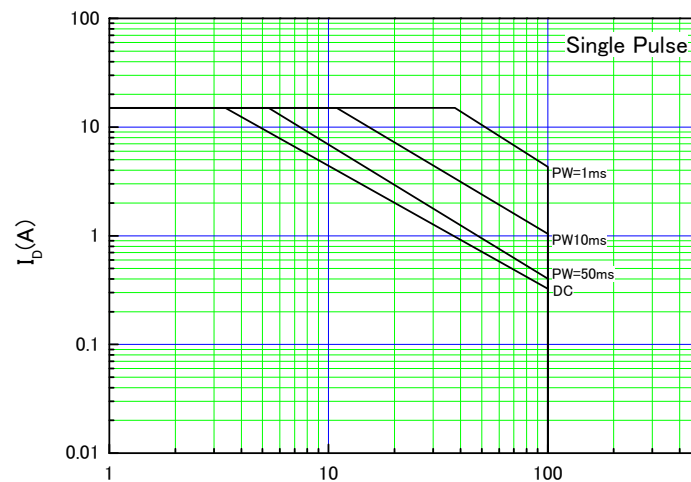


Fig. 28 Maximum Safe Operating Area $I_D = f(V_{DS})$